## 16-/8-Bit Single-Chip Microcomputers

The $\mu$ PD78P324 is a product in which the $\mu$ PD78324's internal mask ROM is replaced by a one-time PROM or EPROM. The one-time PROM product, which enables writing only once, is effective for multiple-device small production of sets or early start of mass-production. The EPROM product, which enables program writing, deletion, and rewriting, is the most suitable for system evaluation.

The $\mu \mathrm{PD} 78 \mathrm{P} 324(\mathrm{~A})$ is more reliable than the $\mu \mathrm{PD} 78 \mathrm{P} 324$. The $\mu \mathrm{PD} 78 \mathrm{P} 324(\mathrm{~A})$ is a product resulting from the $\mu$ PD78324(A) whose internal mask ROM is replaced by a one-time PROM.

For details of functions, please refer to the following User's Manual. Reading this manual is indispensable especially for designing work.
$\mu$ PD78322 User's Manual: IEU-1248

## FEATURES

- $\mu$ PD78324 compatible
- For mass-production, this can be replaced by the $\mu$ PD78324 incorporated in the mask ROM.
- Minimum instruction run time: 250 ns (with the external clock operating at 16 MHz ): $\mu$ PD78P324 \& 78P324(A) 320 ns (with the external clock operating at 12.5 MHz ): $\mu$ PD78P324(A1) \& 78P324(A2)
- Internal PROM: $32768 \times 8$ bits
- Writing enabled only once (windowless one-time PROM product)
- Elimination by ultraviolet light and electrical rewriting enabled (EPROM product with window): $\mu$ PD78P324 only
- ECC circuit incorporated
- High internal PROM content reliablility possible
- PROM programming characteristic: $\mu$ PD27C1001A compatible
- QTOP ${ }^{\text {TM }}$ microcomputer compatible

Remark A QTOP microcomputer is a single-chip microcomputer with one-time PROM for which program writing, marking, screening, and verifying is completely supported by NEC.

## APPLICATION FIELDS

- $\mu$ PD78P324: Fields dealing with motor control equipment.
- $\mu$ PD78P324(A), 78P324(A1), and 78P324(A2): Automotive and transportation equipments, etc.

This document describes the $\mu$ PD78P324, 78P324(A), $\mu$ PD78P324(A1), and $\mu$ PD78P324(A2) as well. However, unless there are particular differences, the $\mu$ PD78P324 is described as a representative product. PROM is the representative term used for the part common to both the one-time PROM product and the EPROM product.

## ORDERING INFORMATION

| Part No. | Package | Internal ROM | Operating Temperature (TA) |
| :--- | :--- | :--- | :--- |
| $\mu$ PD78P324GJ-5BJ | 74-pin plastic QFP $(20 \times 20 \mathrm{~mm})$ | One-time PROM | -10 to $+70^{\circ} \mathrm{C}$ |
| $\mu$ PD78P324LP | 68-pin plastic QFJ( $\square 950 \mathrm{mil})$ | One-time PROM | -10 to $+70^{\circ} \mathrm{C}$ |
| $\mu$ PD78P324KC | 68-pin ceramic WOFN | EPROM | -10 to $+70^{\circ} \mathrm{C}$ |
| $\mu$ PD78P324KD | 74-pin ceramic WOFN | EPROM | -10 to $+70^{\circ} \mathrm{C}$ |
| $\mu$ PD78P324GJ(A)-5BJ | 74-pin plastic QFP $(20 \times 20 \mathrm{~mm})$ | One-time PROM | -40 to $+85^{\circ} \mathrm{C}$ |
| $\mu$ PD78P324GJ(A1)-5BJ | 74-pin plastic QFP $(20 \times 20 \mathrm{~mm})$ | One-time PROM | -40 to $+110^{\circ} \mathrm{C}$ |
| $\mu$ PD78P324GJ(A2)-5BJ | 74-pin plastic QFP $(20 \times 20 \mathrm{~mm})$ | One-time PROM | -40 to $+125^{\circ} \mathrm{C}$ |
| $\mu$ PD78P324LP(A) | 68-pin plastic QFJ( $\square 950 \mathrm{mil})$ | One-time PROM | -40 to $+85^{\circ} \mathrm{C}$ |
| $\mu$ PD78P324LP(A1) | 68 -pin plastic QFJ( $\square 950$ mil) | One-time PROM | -40 to $+110^{\circ} \mathrm{C}$ |
| $\mu$ PD78P324LP(A2) | 68 -pin plastic QFJ( $\square 950$ mil) | One-time PROM | -40 to $+125^{\circ} \mathrm{C}$ |

## QUALITY GRADE

| Part No. | Quality Grade |
| :--- | :---: |
| $\mu$ PD78P324GJ-5BJ | Standard |
| $\mu$ PD78P324LP | Standard |
| $\mu$ PD78P324KC | Standard |
| $\mu$ PD78P324KD | Standard |
| $\mu$ PD78P324GJ(A)-5BJ | Special |
| $\mu$ PD78P324GJ(A1)-5BJ | Special |
| $\mu$ PD78P324GJ(A2)-5BJ | Special |
| $\mu$ PD78P324LP(A) | Special |
| $\mu$ PD78P324LP(A1) | Special |
| $\mu$ PD78P324LP(A2) | Special |

Please refer to "Quality grade on NEC Semiconductor Devices" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

## DIFFERENCES AMONG $\mu$ PD78P324, 78P324(A), 78P324(A1), AND 78P324(A2)

| Product Name <br> Parameter | $\mu \mathrm{PD} 78 \mathrm{P} 324$ | $\mu \mathrm{PD} 78 \mathrm{P} 324(\mathrm{~A})$ | $\mu \mathrm{PD} 78 \mathrm{P} 324(\mathrm{~A} 1)$ | $\mu \mathrm{PD} 78 \mathrm{P} 324(\mathrm{~A} 2)$ |
| :---: | :---: | :---: | :---: | :---: |
| Quality grade | Standard | Special |  |  |
| Operating ambient temperature (TA) | -10 to $+70^{\circ} \mathrm{C}$ | -40 to $+85^{\circ} \mathrm{C}$ | -40 to $+110{ }^{\circ} \mathrm{C}$ | -40 to $+125{ }^{\circ} \mathrm{C}$ |
| Operating frequency | 8 to 16 MHz |  | 8 to 12.5 MHz |  |
| Minimum instruction execution time | 250 ns (when operated at 16 MHz ) |  | 320 ns (when operated at 12.5 MHz ) |  |
| Permissible pin injection current characteristics on overvoltage application | None | Provided |  |  |
| DC characteristics | Differ in the analog pin input leak current, the VDD supply current, and the data retention current. |  |  |  |
| AC characteristics | Differ in the bus timing. |  |  |  |
| A/D converter characteristics | Differ in the analog input voltage and the A/D converter data retention current. |  |  |  |
| One-time PROM product | Provided |  |  |  |
| EPROM product | Provided | None |  |  |

## PIN CONFIGURATION (Top View)

(1) Normal operation mode
(a) 74-pin plastic OFP(20 $\times 20 \mathrm{~mm}$ ); 74-pin ceramic WQFN


Caution As a measure against noise, please connect the NC pin to Vss. (It is also possible to leave this pin unconnected.)

Remark Pin-compatible with $\mu$ PD78324GJ.
(b) 68-pin plastic $\mathrm{QFJ}(\square 950 \mathrm{mil})$; 68-pin ceramic WQFN


Remark Pin-compatible with $\mu$ PD78324LP.

| P00-P07 | : Port0 |
| :--- | :--- |
| P20-P27 | : Port2 |
| P30-P34 | : Port3 |
| P40-P47 | : Port4 |
| P50-P57 | : Port5 |
| P70-P77 | : Port7 |
| P80-P85 | : Port8 |
| P90-P93 | : Port9 |
| NMI | : Nonmakable Interrupt |
| INTP0-INTP6 | : Interrupt from Peripherals |
| RTP0-RTP7 | : Realtime Port |
| TI | : Timer Input |
| TxD | : Transmit Data |
| RxD | : Receive Data |
| SB0/SO | : Serial Bus/Serial Output |
| SB1/SI | : Serial Bus/Serial Input |
| SCK : Serial Clock <br> TO00-TO03 : <br> TO10, TO11 : Timer Output |  |


| RESET | Reset |
| :---: | :---: |
| X1, X2 | : Crystal |
| $\overline{\text { WDTO }}$ | : Watchdog Timer Output |
| $\overline{\mathrm{EA}}$ | : External Access |
| TMD | : Turbo Mode |
| TAS | : Turbo Access Strobe |
| $\overline{\text { WR }}$ | : Write Strobe |
| $\overline{\mathrm{RD}}$ | Read Strobe |
| ASTB | : Address Strobe |
| AD0-AD7 | : Address/Data Bus |
| A8-A15 | : Address Bus |
| AN0-AN7 | : Analog Input |
| AVref | : Analog Reference Voltage |
| AVss | : Analog Vss |
| AVdo | : Analog Vdd |
| Vdo | : Power Supply |
| Vss | : Ground |
| NC | : Non-connection |

(2) $\operatorname{PROM}$ programming mode $(\overline{\operatorname{RESET}}=\mathrm{H}, \mathrm{AVDD}=\mathrm{L})$
(a) 74-pin plastic QFP ( $20 \times 20 \mathrm{~mm}$ ); 74-pin ceramic WQFN


Cautions 1. Codes marked by brackets refer to processing by pins unused in PROM programming mode.
L : Connect to Vss individually via a resistor.
G : Connect to Vss.
Open : Do not connect anything.
2. As a measure against noise, please connect the NC pin to Vss. (It is also possible to leave this pin unconnected.)
(b) 68-pin plastic $\operatorname{QFJ}(950$ mil); 68-pin ceramic WQFN


Caution Codes marked by brackets refer to processing by pins unused in PROM programming mode.
L : Connect to Vss individually via a resistor.
G : Connect to Vss.
Open : Do not connect anything.
$\left.\begin{array}{llll}\text { AO-A16 } & : \text { Address Bus } & \overline{\text { RESET }} & : \\ \overline{\text { DO-D7 }} & : \text { Data Bus } & \text { AVDD } & :\end{array}\right\}$ Programming Mode Set


Remark *: When in PROM programming mode

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## 1. LIST OF PIN FUNCTIONS

### 1.1 NORMAL OPERATION MODE

(1) Port pins

| Pin Name | I/O | Function | Shared Pin Name |
| :---: | :---: | :---: | :---: |
| P00-P07 | I/O | Port 0. <br> 8-bit I/O port. <br> I/O specifiable per bit. <br> (Operable as a real-time output port as well.) | RTP0-RTP7 |
| P20 | Input | Port 2. <br> 8-bit input-only port. | NMI |
| P21 |  |  | INTP0 |
| P22 |  |  | INTP1 |
| P23 |  |  | INTP2 |
| P24 |  |  | INTP3 |
| P25 |  |  | INTP4 |
| P26 |  |  | INTP5 |
| P27 |  |  | INTP6/TI |
| P30 | I/O | Port 3. <br> 5-bit I/O port. I/O specifiable per bit. | TxD |
| P31 |  |  | $R \times D$ |
| P32 |  |  | SO/SB0 |
| P33 |  |  | SI/SB1 |
| P34 |  |  | $\overline{\text { SCK }}$ |
| P40-P47 | I/O | Port 4. <br> 8-bit I/O port. <br> I/O specifiable in units of eight bits. | AD0-AD7 |
| P50-P57 | I/O | Port 5. <br> 8-bit I/O port. I/O specifiable per bit. | A8-A15 |
| P70-P77 | Input | Port 7. <br> 8-bit input-only port. | AN0-AN7 |
| P80 | I/O | Port 8. <br> 6-bit I/O port. I/O specifiable per bit. | TOOO |
| P81 |  |  | TO01 |
| P82 |  |  | TO02 |
| P83 |  |  | TO03 |
| P84 |  |  | TO10 |
| P85 |  |  | TO11 |
| P90 | I/O | Port 9. <br> 4-bit I/O port. I/O specifiable per bit. | $\overline{\mathrm{RD}}$ |
| P91 |  |  | $\overline{W R}$ |
| P92 |  |  | $\overline{\text { TAS }}$ |
| P93 |  |  | $\overline{\text { TMD }}$ |

(2) Pins other than ports (1/2)

| Pin Name | I/O | Function | Shared Pin Name |
| :---: | :---: | :---: | :---: |
| RTP0-RTP7 | Output | Real-time output port performing pulse outputs synchronously with the trigger symbols from the real-time pulse unit (RPU). | P00-P07 |
| INTP0 | Input | External interrupt request input of edge detection. A valid edge can be selected by the external interrupt mode register. | P21 |
| INTP1 |  |  | P22 |
| INTP2 |  |  | P23 |
| INTP3 |  |  | P24 |
| INTP4 |  |  | P25 |
| INTP5 |  |  | P26 |
| INTP6 |  |  | P27/TI |
| NMI | Input | Non-maskable interrupt request input of edge detection. A valid edge can be selected by the external interrupt mode register. | P20 |
| TI | Input | External counter clock input to Timer 1 (TM1). | P27/INTP6 |
| RxD | Input | Serial data input of the asynchronous serial interface (UART). | P31 |
| TxD | Output | Serial data output of the asynchronous serial interface (UART). | P30 |
| SI | Input | Serial data input in three-wire mode of the clock synchronous serial interface. | P33/SB1 |
| SO | Output | Serial data input in three-wire mode of the clock synchronous serial interface. | P32/SB0 |
| SB0 | I/O | Serial data output in three-wire mode of the clock synchronous serial interface. | P32/SO |
| SB1 |  |  | P33/SI |
| $\overline{\text { SCK }}$ | I/O | Serial clock I/O of the clock synchronous serial interface. | P34 |
| AD0-AD7 | 1/O | Address data bus for accessing external memory. | P40-P47 |
| A8-A15 | Output | Address bus for accessing external memory. | P50-P57 |
| $\overline{\mathrm{RD}}$ | Output | Read signal output to external memory. | P90 |
| $\overline{W R}$ |  | Write signal output to external memory. | P91 |
| $\overline{\text { TAS }}$ | Output | Control signal output for accessing the turbo access manager ( $\mu$ PD71P301) ${ }^{\text {Note }}$. | P92 |
| TMD |  |  | P93 |
| TO00 | Output | Output from the real-time pulse unit. | P80 |
| TO01 |  |  | P81 |
| TO02 |  |  | P82 |
| TO03 |  |  | P83 |
| TO10 |  |  | P84 |
| TO11 |  |  | P85 |

Note The turbo access manager ( $\mu \mathrm{PD} 71 \mathrm{P} 301$ ) is a maintenance product.
(2) Pins other than ports (2/2)

| Pin Name | I/O | Function | Shared Pin Name |
| :---: | :--- | :--- | :---: |
| ASTB | Output | Access to external memory. Timing signal output for <br> externally latching the lower address which is output <br> from the ADO-AD7 pin. | - |
| $\overline{\text { WDTO }}$ | Output | Output of the signal which indicates that the watchdog <br> timer generated a non-maskable interrupt. | - |
| $\overline{\text { EA }}$ | Input | Normally, the EA pin is connected to Vod. By connecting <br> the EA pin to Vss, the system is placed in ROM-less mode <br> to access external memory. The level of the EA pin <br> cannot be switched over during operation. | - |
| ANO-AN7 | Input | Analog input to the A/D converter | - |
| AVREF | Input | Reference voltage input of the A/D converter. | - |
| AVDD | - | Analog power of the A/D converter. | - |
| AVss | - | Ground of the A/D converter. | - |
| $\overline{\text { RESET }}$ | Input | Input of the system reset. | - |
| X1 | Input | Connection of the crystal oscillator for system clock <br> generation. When clocks are supplied externally, they are <br> input to the X1 pin and their reverse signals are input to <br> the X2 pin. (The X2 pin can also be left unconnected.) | - |
| X2 | - | Positive power voltage. | - |
| VDD | - | Ground. | - |
| Vss | - | Internally unconnected. Please connect this to Vss. (It can <br> also be left unconnected.) | - |
| NC | - |  |  |

### 1.2 PROM PROGRAMMING MODE (RESET = H, AVdd = L)

| Pin Name | I/O | Function |
| :---: | :---: | :---: |
| AV ${ }_{\text {dD }}$ | Input | PROM programming mode setting |
| $\overline{\text { RESET }}$ |  |  |
| A0-A16 | Input | Address bus |
| D0-D7 | I/O | Data bus |
| $\overline{\text { PGM }}$ | Input | Program input |
| $\overline{\mathrm{CE}}$ | Input | PROM enable input |
| $\overline{\mathrm{OE}}$ | Input | Read strobe to PROM |
| Vpp | - | Write power |
| Vdo |  | Positive power voltage |
| Vss |  | Ground |
| NC |  | Internally unconnected. Please connect this to Vss. It can also be left unconnected.) |

### 1.3 PIN I/O CIRCUIT AND UNUSED-PIN PROCESSING

The I/O circuits of the pins are shown in Table 1-1 and Figure 1-1 some of them in a simplified form.

Table 1-1. I/O Circuit Types of Pins and Recommended Connection Methods When Unused

| Pin Name | I/O Circuit Type | Recommended Connection Method When Unused |
| :---: | :---: | :---: |
| P00/RTP0-P07/RTP7 | 5 | Input status: Connected to VdD or Vss via a resistor individually. Output status: No connection required. |
| P20/NMI <br> P21/INTP0-P26/INTP5 <br> P27/INTP6/TI | 2 | Connected to Vss. |
| $\begin{aligned} & \mathrm{P} 30 / \mathrm{TxD} \\ & \mathrm{P} 31 / \mathrm{RxD} \end{aligned}$ | 5 |  |
| $\begin{aligned} & \mathrm{P} 32 / \mathrm{SO} / \mathrm{SB} 0 \\ & \mathrm{P} 33 / \mathrm{SI} / \mathrm{SB} 1 \\ & \mathrm{P} 34 / \overline{\mathrm{SCK}} \end{aligned}$ | 8 | Input status: Connected to VDD or Vss via a resistor individually. Output status: No connection required. |
| P40/AD0-P47/AD7 <br> P50/A8-P57/A15 | 5 |  |
| P70/AN0-P77/AN7 | 9 | Connected to Vss. |
| P80/TO00-P83/TO03 P84/TO10, P85/TO11 | 5 |  |
| P90/RD <br> P91/NR <br> P92/TAS <br> P93/TMD | 5 | Input status: Connected to VDD or Vss via a resistor individually. Output status: No connection required. |
| WDTO | 3 |  |
| ASTB | 4 |  |
| $\overline{\mathrm{EA}}$ | 1 | - |
| RESET | 2 | - |
| AVdd | - | Connected to Vod. |
| $A V_{\text {ReF }}$ <br> AVss | - | Connected to Vss. |
| VPP | - | Connected to Vod. |
| NC | - | Connected to Vss. (It is also possible to leave this unconnected.) |

Figure 1-1. I/O Circuits of Pins
Type 1

## 2. DIFFERENCES BETWEEN $\mu$ PD78P324 AND $\mu$ PD78324

The $\mu$ PD78P324 is a product in which the $\mu$ PD78324's internal mask ROM is replaced by a 32 KB PROM. Therefore, these two products share the same functions, except for differences deriving from the ROM specifications (for example, Write and Verify, etc.). Their differences are shown in Table 2-1 below.

Table 2-1. Differences between $\mu$ PD78P324 and $\mu$ PD78324

| $\qquad$ <br> Product Name <br> Parameter | $\mu \mathrm{PD} 78 \mathrm{P} 324$ |  | $\mu$ PD78324 |
| :---: | :---: | :---: | :---: |
| Internal program memory (Electric write) | One-time PROM (Write enabled only once) | EPROM <br> (Rewrite enabled) | Mask ROM |
| ECC circuit | With |  | Without |
| PROM programming pin | With |  | Without |
| Package | -68-pin plastic QFJ <br> -74-pin plastic QFP | -68-pin ceramic WOFN <br> -74-pin ceramic WQFN | -68-pin plastic QFJ <br> -74-pin plastic QFP |
| Electrical characteristics | Differ in current consumption, etc. |  |  |
| Others | As they differ in their circuit size and mask layout, their noise resistance volume and noise reflection differ. |  |  |

[^0]
## 3. PROM PROGRAMMING

The $\mu$ PD78P324 incorporates an electrically writable 32768-by-8-bit program PROM and an 8192-by-6-bit ECC (error correcting code) PROM.

ECC corrects the errors in codes written in the program PROM, thus improving the reliability of the PROM content. Figure 3-1 shows the memory map in programming mode.

Figure 3-1. Memory Map in Programming Mode


Note On the ECC PROM, the lower 6 bits are valid.

When programming, set the $\overline{R E S E T}$ pin and the $A V_{D D}$ pin to PROM programming mode. The programming characteristics of the $\mu$ PD78P324 are compatible with the $\mu$ PD27C1001A. However, the programming mode is compatible only with the byte program mode of the $\mu$ PD27C1001A. For setting on the PROM programmer, please select the byte program mode of the 27C1001A mode.

When using the ECC circuit, reset the lowest bit (A000.0) of the lowest byte of the ECW (ECC control word) to enable the operation of the ECC circuit. ECW is a 4-byte register which controls the operation of the ECC circuit. ECC and ECW are generated automatically with the ECCGEN (ECC generator) which comes with the RA78K3 assembler package. (ECC is generated in the lower 6 bits; and the upper 2 bits are fixed to 1.)

Table 3-1. Pin Functions in Programming Mode

| Function | Normal Operation Mode | Programming Mode |
| :---: | :---: | :---: |
| Address input | P00-P07, P80, P20, P81-P85, P33, P34 | A0-A16 |
| Data input | P40-P47 | D0-D07 |
| Program pulse | P32 | PGM |
| Chip enable | P31 | $\overline{\mathrm{CE}}$ |
| Output enable | P30 | $\overline{\mathrm{OE}}$ |
| Program voltage | Vpp |  |
| Mode voltage | $\overline{\mathrm{RESET}}$, AVDD |  |

### 3.1 OPERATION MODE

When placing the microcomputer in programming Write/Verify mode, set it to $\overline{R E S E T}=H$ and $A V D D=L$. In this mode, an operation mode in Table 3-2 can be selected by further setting the CE and OE pins.

When reading the content of the PROM, set it to Read mode. Process the unused pins in accordance with the instructions in the PIN CONFIGURATION.

Table 3-2. Operation Mode of PROM Programming

| Mode | $\overline{\text { RESET }}$ | AVDD | $\overline{\mathrm{CE}}$ | $\overline{\mathrm{OE}}$ | $\overline{\text { PGM }}$ | VPP | VDD | D0-D7 |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Program Write | H | L | L | H | L | +12.5 V | +6.5 V | Data input |
| Program verify |  |  | L | L | H |  |  | Data output |
| Program inhibit |  |  |  | $\begin{aligned} & \mathrm{L} \\ & \mathrm{H} \end{aligned}$ | $\begin{aligned} & \mathrm{L} \\ & \mathrm{H} \end{aligned}$ |  |  | High impedance |
| Read |  |  | L | L | H | +5 V | +5 V | Data output |
| Output disable |  |  | L | H | X |  |  | High impedance |
| Standby |  |  | H | X | X |  |  | High impedance |

Remark x : L or H

### 3.2 PROCEDURE FOR PROM WRITE

The procedure for writing into the PROM is as follows (see Figure 3-3).
(1) Fix to $\overline{\mathrm{RESET}}=\mathrm{H}$; and AV DD $=\mathrm{L}$. Other unused pins are processed as directed by the PIN CONFIGURATION.
(2) Supply +6.5 V to the VDD pin; and +12.5 V to the VPP pin. Enter the low level into the $\overline{\mathrm{CE}}$ pin.
(3) Enter the initial address into A0-A16.
(4) Enter the Write data into D0-D7.
(5) Enter the 0.1 ms program pulse (active low) into the $\overline{\mathrm{PGM}}$ pin.
(6) Verify mode. Check if the Write data has been written or not.

Enter the active low pulse into the $\overline{\mathrm{OE}}$ pin and read the Write data from DO-D7.

- When written: Move to (8).
- When not able to write: Repeat (4) to (6). If it is not possible to write even when the repetition has been made ten times, move to (7).
(7) Stop the Write operation as a defective device.
(8) Increment the address.
(9) Repeat (4) to (8) until the final address.

The timing of the above (2) to (7) steps is shown in Figure 3-2.

Figure 3-2. PROM Write/Verify Timing


Figure 3-3. Write Procedure Flowchart


### 3.3 PROCEDURE FOR PROM READ

The PROM content is read to the external data bus (D0-D7) in accordance with the following procedure:
(1) Fix to $\overline{R E S E T}=H$; and $A V_{D D}=L$. Other unused pins are processed as directed by the PIN CONFIGURATION.
(2) Supply +5 V to the VdD and VPP pins.
(3) Enter the address of the data read into the A0-A16 pin.
(4) Read mode ( $\overline{\mathrm{CE}}=\mathrm{L}$; $\overline{\mathrm{OE}}=\mathrm{L}$ )
(5) Data is output to the D0-D7 pin.

The timing of the above (2) to (5) is shown in Figure 3-4.
Figure 3-4. PROM Read Timing


## 4. ERASURE CHARACTERISTICS ( $\mu$ PD78P324KC/KD ONLY)

The $\mu$ PD78P324KC/KD can erase (FFH) the content of the data written in the program memory and perform rewriting.

The data content is erased by radiating light with a wavelength shorter than about 400 nm on the erasure window. Normally, ultraviolet light with a wavelength of 254 nm is radiated. The volume of light required for erasing the data content completely is as follows:

- Ultraviolet ray intensity x erasure time: $15 \mathrm{~W} \cdot \mathrm{~s} / \mathrm{cm}^{2}$ or more
- Erasure time: 15 to 20 mins (This is so when using an ultraviolet lamp of $12,000 \mu \mathrm{~W} / \mathrm{cm}^{2}$. However, a longer time may be required due to performance degradation of the ultraviolet ray lamp or dirt deposited on the erasure window, etc.)

For erasure, make sure to place the ultraviolet ray lamp at a location within 2.5 cm from the erasure window. If the ultraviolet ray lamp is equipped with a filter, make sure that the filter is removed for radiation.

## 5. ERASURE WINDOW SEAL ( $\mu$ PD78P324KC/KD ONLY)

If the erasure window part of the $\mu$ PD78P324KC/KD is exposed to sunlight or fluorescent light for too long, the EPROM data may be erased or the internal circuits may malfunction. To prevent such an accident, please ensure that the erasure window part is covered with a protective seal except when the data is going to be erased.

The EPROM package with window is shipped with a protective seal that is NEC's guarantee of quality.

## 6. ONE-TIME PROM PRODUCT SCREENING

Structurally, it is not possible for NEC to test the one-time PROM products ( $\mu$ PD78P324GJ-5BJ/(A)/(A1)/ (A2) and 78P324LP/(A)/(A1)/(A2) completely before shipment. Therefore, it recommended that, after writing the required data, the screening be implemented to verify the PROM after storing the product in the following temperature and condition.

| Storage Temperature | Storage Time |
| :---: | :---: |
| $125^{\circ} \mathrm{C}$ | 24 hrs |

NEC provides at a charge services including the one-time PROM writing, sealing, screening and verifying under the title of QTOP microcomputer. For further details, please contact an NEC salesperson.

## 7. ELECTRICAL SPECIFICATIONS

(1) $\mu$ PD78P324 Electrical Specifications (1/9)

## Absolute Maximum Ratings ( $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ )



Notes 1. Except P70/AN0-P77/AN7.
2. P70/AN0-P77/AN7 pins.

Caution If the absolute maximum rating of any one of the parameters is exceeded even momentarily, the quality of the product may be degraded. In other words, the product may be physically damaged if any of the absolute maximum ratings is exceeded. Be sure to use the product without exceeding these ratings.

## Recommended Operating Range

| Oscillation Frequency | $\mathrm{T}_{\mathrm{A}}$ | $\mathrm{VDD}_{\mathrm{DD}}$ |
| :---: | :---: | :---: |
| $8 \mathrm{MHz} \leq \mathrm{fxx} \leq 16 \mathrm{MHz}$ | -10 to $+70^{\circ} \mathrm{C}$ | $+5.0 \mathrm{~V} \pm 10 \%$ |

## Capacitance ( $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$, $\mathrm{Vss}=\mathrm{V}_{\mathrm{DD}}=0 \mathrm{~V}$ )

| Parameter | Symbol | Condition | MIN. | TUP. | MAX. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Input capacitance | $\mathrm{Cl}_{1}$ | $\begin{aligned} & \mathrm{f}=1 \mathrm{MHz} ; \\ & 0 \mathrm{~V} \text { except measured pins } \end{aligned}$ |  |  | 10 | pF |
| Output capacitance | Co |  |  |  | 20 | pF |
| I/O capacitance | Cıo |  |  |  | 20 | pF |

(1) $\mu$ PD78P324 Electrical Specifications (2/9)

Oscillator Characteristics ( $\mathrm{T}_{\mathrm{A}}=-10$ to $+70^{\circ} \mathrm{C}, \mathrm{VDD}=+5 \mathrm{~V} \pm 10 \%, \mathrm{Vss}=0 \mathrm{~V}$ )

| Oscillator | Recommended Circuit | Parameter | MIN. | MAX. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Ceramic oscillator or crystal oscillator |  | Oscillation frequency ( $\mathrm{fxx}^{\text {) }}$ | 8 | 16 | MHz |
| External clock |  | X1 input frequency ( fx ) | 8 | 16 | MHz |
|  | No connection required HCMOS inverter | X1 input rise time, fall time (txr, txf) | 0 | 20 | ns |
|  |  | X1 input high-/low-level width (twxh, twxL) | 25 | 80 | ns |

Caution When using the system clock oscillation circuit, wire the part encircled in the dotted line in the following manner to avoid the influence of the wiring capacity, etc.

- Make the wiring as short as possible.
- Avoid intersecting other signal conductors. Avoid approaching lines in which very high fluctuating currents run.
- Make sure that the grounding point of the oscillation circuit capacitor always has the same electrical potential as Vss. Avoid grounding with a grand pattern in which very high currents run.
- Do not fetch signals from the oscillation circuit.
(1) $\mu$ PD78P324 Electrical Specifications (3/9)


## Recommended Oscillation Circuit Constants

## Ceramic Oscillator

| Manufacturer | Product Name | Frequency (MHz) | Recommended Constant |  |
| :---: | :---: | :---: | :---: | :---: |
|  |  |  | C1 (pF) | C2 (pF) |
| Murata Mfg. Co., Ltd. | CSA8.00MT CSA12.0MT | $\begin{gathered} 8.0 \\ 12.0 \end{gathered}$ | 30 | 30 |
|  | CSA14.74MXZ040 CSA16.00MX040 | $\begin{gathered} 14.74 \\ 16.0 \end{gathered}$ | 15 | 15 |
|  | CST8.00MTW CST12.0MTW CST14.74MXW0C3 CST16.00MXW0C3 | $\begin{gathered} 8.0 \\ 12.0 \\ 14.74 \\ 16.0 \end{gathered}$ | Incorporated | Incorporated |

(1) $\mu$ PD78P324 Electrical Specifications (4/9)

DC Characteristics ( $\mathrm{T}_{\mathrm{A}}=\mathbf{- 1 0}$ to $+70^{\circ} \mathrm{C}, \mathrm{VDD}=+\mathbf{5} \mathrm{V} \pm \mathbf{1 0} \%$, $\mathrm{Vss}=\mathbf{0} \mathrm{V}$ )

| Parameter | Symbol | Condition |  |  | MIN. | TYP. | MAX. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Low-level input voltage | VIL |  |  |  | 0 |  | 0.8 | V |
| High-level input voltage | $\mathrm{V}_{\mathrm{H} 1}$ | Note 1 |  |  | 2.2 |  |  | V |
|  | $\mathrm{V}_{1}{ }^{\text {2 }}$ | Note 2 |  |  | 0.8 VDd |  |  |  |
| Low-level output voltage | Vol | $\mathrm{loL}=2.0 \mathrm{~mA}$ |  |  |  |  | 0.45 | V |
| High-level output voltage | Vон | $\mathrm{IOH}=-400 \mu \mathrm{~A}$ |  |  | VDD-1.0 |  |  | V |
| Input leakage current | ILI | Note 3 |  | $\mathrm{V} \leq \mathrm{V}_{\text {I }} \leq \mathrm{V}_{\mathrm{DD}}$ |  |  | $\pm 10$ | $\mu \mathrm{A}$ |
| Analog pin input leakage current | Ilian | Note 4 |  | $\leq \mathrm{V}_{\text {IAN }} \leq \mathrm{AV}_{\text {ref }}$ |  |  | $\pm 10$ | $\mu \mathrm{A}$ |
| Output leakage current | ILo | $0 \mathrm{~V} \leq \mathrm{V}_{\mathrm{o}} \leq \mathrm{V}_{\text {do }}$ |  |  |  |  | $\pm 10$ | $\mu \mathrm{A}$ |
| Vod supply current | IdD1 | Operation mode |  |  |  | 70 | 95 | mA |
|  | IdD2 | HALT mode |  |  |  | 35 | 55 | mA |
| Data retention voltage | Vdddr | STOP mode |  |  | 2.5 |  |  | V |
| Data retention current | IDDDR | STOP mode |  | Vddor $=2.5 \mathrm{~V}$ |  | 2 | 10 | $\mu \mathrm{A}$ |
|  |  |  |  | VDDDR=5.0 $\mathrm{V} \pm 10 \%$ |  | 10 | 50 | $\mu \mathrm{A}$ |

Notes 1. Pins other than pins in Note 2.
2. RESET, X1, X2, P20/NMI, P21/INTP0, P22/INTP1, P23/INTP2, P24/INTP3, P25/INTP4, P26/INTP5, P27/ INTP6/TI, P32/SO/SB0, P33/SI/SB1, P34/SCK pins.
3. Pins except P20/NMI, EA/Vpp, X1, X2
4. When not sampling the analog input

## (1) $\mu$ PD78P324 Electrical Specifications (5/9)

AC Characteristics ( $\mathrm{T}_{\mathrm{A}}=-10$ to $+70^{\circ} \mathrm{C}, \mathrm{VDD}=+5 \mathrm{~V} \pm 10 \%$, $\mathrm{Vss}=\mathbf{0} \mathrm{V}, \mathrm{C}_{\mathrm{L}}=100 \mathrm{pF}$ )
Non-serial Read/Write Operation (when connecting general-purpose memory)

| Parameter | Symbol | Condition | MIN. | MAX. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| System clock cycle time | tcyk |  | 125 | 250 | ns |
| Address setup time (vs. ASTB $\downarrow$ ) | tSAST |  | 32 |  | ns |
| Address hold time (vs. ASTB $\downarrow$ ) | thsta |  | 32 |  | ns |
| Address $\rightarrow \overline{\mathrm{RD}} \downarrow$ delay time | tDar |  | 85 |  | ns |
| $\overline{\mathrm{RD}} \downarrow \rightarrow$ address float time | tFRA |  |  | 10 | ns |
| Address $\rightarrow$ data input time | tDaid |  |  | 222 | ns |
| $\overline{\mathrm{RD}} \downarrow \rightarrow$ data input time | tDRID |  |  | 112 | ns |
| ASTB $\downarrow \rightarrow \overline{\mathrm{RD}} \downarrow$ delay time | tostr |  | 42 |  | ns |
| Data hold time (vs. $\overline{\mathrm{RD}} \uparrow$ ) | thrid |  | 0 |  | ns |
| $\overline{\mathrm{RD}} \uparrow \rightarrow$ address active time | tDRA |  | 50 |  | ns |
| $\overline{\mathrm{RD}}$ low-level width | twRL |  | 147 |  | ns |
| ASTB high-level width | twsth |  | 37 |  | ns |
| Address $\rightarrow \overline{\mathrm{WR}} \downarrow$ delay time | tdaw |  | 85 |  | ns |
| ASTB $\downarrow \rightarrow$ data output time | tostod |  |  | 102 | ns |
| $\overline{\mathrm{WR}} \downarrow \rightarrow$ data output time | towod |  |  | 40 | ns |
| ASTB $\downarrow \rightarrow \overline{\mathrm{WR}} \downarrow$ delay time | tostw |  | 42 |  | ns |
| Data setup time (vs. $\overline{W R} \uparrow$ ) | tsodw |  | 147 |  | ns |
| Data hold time (vs. $\overline{\mathrm{WR}} \uparrow$ ) | thwod |  | 32 |  | ns |
| $\overline{\mathrm{WR}} \uparrow \rightarrow$ ASTB $\uparrow$ delay time | tDwst |  | 42 |  | ns |
| $\overline{\mathrm{WR}}$ low-level width | twWL |  | 147 |  | ns |

(1) $\mu$ PD78P324 Electrical Specifications (6/9)
tcyk-dependent Bus Timing Definition

| Symbol | Calculation formula | MIN./MAX. | Unit |
| :---: | :---: | :---: | :---: |
| tSAST | 0.5T-30 | MIN. | ns |
| thsta | 0.5T-30 | MIN. | ns |
| tDar | T-40 | MIN. | ns |
| tDaid | $(2.5+n)$ T-90 | MAX. | ns |
| tdrid | $(1.5+n)$ T-75 | MAX. | ns |
| tostr | 0.5T-20 | MIN. | ns |
| tDRA | 0.5T-12 | MIN. | ns |
| twrL | $(1.5+n)$ T-40 | MIN. | ns |
| twsth | 0.5T-25 | MIN. | ns |
| toaw | T-40 | MIN. | ns |
| tostod | $0.5 \mathrm{~T}+40$ | MAX. | ns |
| tostw | 0.5T-20 | MIN. | ns |
| tsodw | 1.5T-40 | MIN. | ns |
| thwod | 0.5T-30 | MIN. | ns |
| towst | 0.5T-20 | MIN. | ns |
| twwL | $(1.5+n)$ T-40 | MIN. | ns |

Remarks 1. $T=$ tcyk $=1 /$ fclk (fclk refers to the internal system clock frequency)
2. $n$ refers to the count of weight cycles defined by the user software.
3. Among the parameters for bus timing, only those listed in this table are dependent on tcyk.
(1) $\mu$ PD78P324 Electrical Specifications (7/9)

Serial Operation ( $\mathrm{T}_{\mathrm{A}}=\mathbf{- 1 0}$ to $+70^{\circ} \mathrm{C}, \mathrm{VDD}=+5 \mathrm{~V} \pm 10 \%, \mathrm{Vss}=0 \mathrm{~V}$ )

| Parameter | Symbol | Condition |  | MIN. | MAX. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Serial clock cycle time | tCYSK | SCK output | Internal divide-by-eight | 1 |  | $\mu \mathrm{s}$ |
|  |  | SCK input | External clock | 1 |  | $\mu \mathrm{s}$ |
| Serial clock low-level width | tWSKL | SCK output | Internal divide-by-eight | 420 |  | ns |
|  |  | SCK input | External clock | 420 |  | ns |
| Serial clock high-level width | twSKH | SCK output | Internal divide-by-eight | 420 |  | ns |
|  |  | SCK input | External clock | 420 |  | ns |
| SI setup time (vs. $\overline{\text { SCK }} \uparrow$ ) | tsrxsk |  |  | 80 |  | ns |
| SI hold time (vs. $\overline{\text { SCK }} \uparrow$ ) | tHSKRX |  |  | 80 |  | ns |
| $\overline{\text { SCK }} \downarrow \rightarrow$ SO delay time | tDSKTX | $\mathrm{R}=1 \mathrm{k} \Omega, \mathrm{C}=100 \mathrm{pF}$ |  |  | 210 | ns |

tcyк-dependent Serial Operation

| Symbol | Condition |  | Calculation Formula | MIN./MAX | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| tcysk | $\overline{\text { SCK }}$ output | Internal divide-by-eight | 8T | MIN. | ns |
|  | $\overline{\text { SCK }}$ input | External clock | 8T | MIN. | ns |
| twskL | $\overline{\text { SCK }}$ output | Internal divide-by-eight | 4T-80 | MIN. | ns |
|  | $\overline{\text { SCK }}$ input | External clock | 4T-80 | MIN. | ns |
| twSKH | $\overline{\text { SCK }}$ output | Internal divide-by-eight | 4T-80 | MIN. | ns |
|  | $\overline{\text { SCK }}$ input | External clock | 4T-80 | MIN. | ns |

Remarks 1. $T=t c y k=1 / f c L K$ (fcLk refers to the internal system clock frequency)
2. Among the parameters for serial operation, only those listed in this table are dependent on tcyk.
(1) $\mu$ PD78P324 Electrical Specifications (8/9)

Other Operations ( $\mathrm{T}_{\mathrm{A}}=\mathbf{- 1 0}$ to $+70^{\circ} \mathrm{C}, \mathrm{VdD}=+5 \mathrm{~V} \pm 10 \%, \mathrm{VdD}=0 \mathrm{~V}$ )

| Parameter | Symbol | Condition | MIN. | MAX. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| NMI high-/low-level width | twnin, twnil | Analog noises removed | 4 |  | $\mu \mathrm{s}$ |
| INTP0 high-/low-level width | twioh, twiol |  | 1 |  | $\mu \mathrm{s}$ |
| INTP1 high-/low-level width | twilh, twill |  | 1 |  | $\mu \mathrm{s}$ |
| INTP2 high-/low-level width | twi2H, twi2L |  | 1 |  | $\mu \mathrm{s}$ |
| INTP3 high-/low-level width | twi3h, twi3L |  | 1 |  | $\mu \mathrm{s}$ |
| INTP4 high-/low-level width | twi4h, twi4L |  | 1 |  | $\mu \mathrm{s}$ |
| INTP5 high-/low-level width | twish, twisk |  | 1 |  | $\mu \mathrm{s}$ |
| INTP6 high-/low-level width | twi6H, twi6L |  | 1 |  | $\mu \mathrm{s}$ |
| $\overline{\text { RESET }}$ high-/low-level width | twrsh, twrsL | Analog noises removed | 3.5 |  | $\mu \mathrm{s}$ |
| TI high-/low-level width | twTIH, twTIL |  | 1 |  | $\mu \mathrm{s}$ |
| VDD rise/fall time | trvo, tfvD |  | 200 |  | $\mu \mathrm{s}$ |

## Other tсүк-dependent Operations

| Symbol | Calculation formula | MIN./MAX. | Unit |
| :---: | :---: | :---: | :---: |
| twioh | 8T | MIN. | ns |
| twiol | 8T | MIN. | ns |
| twin | 8T | MIN. | ns |
| twi1L | 8T | MIN. | ns |
| twi2H | 8 T | MIN. | ns |
| twi2L | 8T | MIN. | $n s$ |
| twish | 8T | MIN. | ns |
| twi3L | 8T | MIN. | ns |
| twish | 8 T | MIN. | ns |
| twI4L | 8 T | MIN. | ns |
| twish | 8T | MIN. | ns |
| twist | 8T | MIN. | ns |
| twi6H | 8T | MIN. | ns |
| twi6L | 8T | MIN. | ns |
| twTiH | 8T | MIN. | ns |
| twTIL | 8T | MIN. | ns |

Remarks 1. $T=t$ tcyk $=1 /$ fclk (fclk refers to the internal system clock frequency)
2. Only the parameters listed in this table depend on tсүк.

## (1) $\mu$ PD78P324 Electrical Specifications (9/9)

## AC Timing Test Point




| Parameter | Symbol | Condition |  | MIN. | TYP. | MAX. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Resolution |  |  |  | 10 |  |  | bit |
| Total error ${ }^{\text {Note1 }}$ |  | $4.5 \mathrm{~V} \leq \mathrm{AV}_{\mathrm{REF}} \leq \mathrm{AV} \mathrm{VDD}$ |  |  |  | $\pm 0.4$ | \%FSR |
|  |  | $3.5 \mathrm{~V} \leq \mathrm{AV} \mathrm{V}_{\text {RFF }} \leq \mathrm{AV} \mathrm{VDD}$ |  |  |  | $\pm 0.7$ | \%FSR |
| Quantization error |  |  |  |  |  | $\pm 1 / 2$ | LSB |
| Conversion time | tconv |  |  | 144 |  |  | tcyk |
| Sampling time | tsamp |  |  | 24 |  |  | tcyk |
| Zero-scale error ${ }^{\text {Note1 }}$ |  | $4.5 \mathrm{~V} \leq \mathrm{AV}_{\mathrm{REF}} \leq \mathrm{AV} \mathrm{DDD}$ |  |  | $\pm 1.5$ | $\pm 2.5$ | LSB |
|  |  | $3.4 \mathrm{~V} \leq \mathrm{AV}_{\mathrm{reF}} \leq \mathrm{AV} \mathrm{Vd}^{\text {d }}$ |  |  | $\pm 1.5$ | $\pm 4.5$ | LSB |
| Full-scale error ${ }^{\text {Note }} 1$ |  | $4.5 \mathrm{~V} \leq \mathrm{AV}_{\mathrm{REF}} \leq \mathrm{AV} \mathrm{VD}$ |  |  | $\pm 1.5$ | $\pm 2.5$ | LSB |
|  |  | $3.4 \mathrm{~V} \leq A V_{\text {REF }} \leq A V_{\text {dD }}$ |  |  | $\pm 1.5$ | $\pm 4.5$ | LSB |
| Non-linear error ${ }^{\text {Note } 1}$ |  | $4.5 \mathrm{~V} \leq \mathrm{AV}_{\mathrm{reF}} \leq \mathrm{AV} \mathrm{VdD}$ |  |  | $\pm 1.5$ | $\pm 2.5$ | LSB |
|  |  | $3.4 \mathrm{~V} \leq \mathrm{AV}_{\mathrm{REF}} \leq \mathrm{AV} \mathrm{VDD}$ |  |  | $\pm 1.5$ | $\pm 4.5$ | LSB |
| Analog input voltage ${ }^{\text {Note } 2}$ | VIAN |  |  | 0 |  | AVdd | V |
| Analog input impedance | Ran | When not sampled |  |  | 10 |  | $\mathrm{M} \Omega$ |
|  |  | When sampled |  |  | Note 3 |  |  |
| Reference voltage | AVref |  |  | 3.4 |  | AVDd | V |
| AVref current | Alref |  |  |  | 1.0 | 3.0 | mA |
| AVdD supply current | Aldd | Operation mode |  |  | 2.0 | 6.0 | mA |
| A/D converter data retention current | Aldddr | STOP mode | AV DDDR $=2.5 \mathrm{~V}$ |  | 2 | 15 | $\mu \mathrm{A}$ |
|  |  |  | $A V_{\text {dodr }}=5 \mathrm{~V} \pm 10 \%$ |  | 10 | 50 | $\mu \mathrm{A}$ |

Notes 1. Quantization error excluded.
2. When $-0.3 \mathrm{~V} \leq \mathrm{V}$ IAN $\leq 0 \mathrm{~V}$, the conversion result becomes 000 H .

When $0 \mathrm{~V}<\mathrm{V}_{\text {IAN }}<\mathrm{AV}_{\text {REF, }}$ the conversion is performed at a resolution of 10 bits.
When $A V_{\text {ref }} \leq V_{\text {Ian }} \leq A V_{D D}$, the conversion result is 3FFH.
3. The analog input impedance in sampling is the same as the equivalent circuit shown in the diagram below. (The values in the diagram are TYP. values; therefore, they are not assured.)

(2) $\mu$ PD78P324(A) Electrical Specifications (1/9)

Absolute Maximum Ratings ( $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ )

| Parameter | Symbol | Condition |  | Rating | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Supply voltage | Vdd |  |  | -0.5 to +7.0 | V |
|  | AVdd |  |  | -0.5 to VDD +0.5 | V |
|  | VPP |  |  | -0.5 to +13.5 | V |
|  | AVss |  |  | -0.5 to +0.5 | V |
| Input voltage | V | Notes 1, 2 |  | -0.5 to VDD +0.5 | V |
| Output voltage | Vo |  |  | -0.5 to VDD +0.5 | V |
| Low-level output current | lob | All output pins |  | 4.0 | mA |
|  |  | Total of all output pins |  | 90 | mA |
| High-level output current | Іон | All output pins |  | -1.0 | mA |
|  |  | Total of all output pins |  | -20 | mA |
| Analog input voltage | Vian | Notes 2, 3 | $A V_{D D}>V_{\text {dD }}$ | -0.5 to VDD +0.5 | V |
|  |  |  | $V_{D D} \geq \mathrm{AV}$ DD | -0.5 to AVDD +0.5 |  |
| A/D converter reference input voltage | AVref |  | $A V_{D D}>V_{D D}$ | -0.5 to VDD +0.5 | V |
|  |  |  | $V_{D D} \geq$ AVDD | -0.5 to AVDD +0.5 |  |
| Operating ambient temperature | TA |  |  | -40 to +85 | ${ }^{\circ} \mathrm{C}$ |
| Storage temperature | $\mathrm{T}_{\text {stg }}$ |  |  | -65 to +150 | ${ }^{\circ} \mathrm{C}$ |

Notes 1. Except P70/AN0-P77/AN7.
2. The overvoltage condition of the allowable pin injectioncurrent characteristics in overvoltage application is excluded.
3. P70/AN0-P77/AN7 pins.

Caution If the absolute maximum rating of any one of the parameters is exceeded even momentarily, the quality of the product may be degraded. In other words, the product may be physically damaged if any of the absolute maximum ratings is exceeded. Be sure to use the product without exceeding these ratings.
(2) $\mu$ PD78P324(A) Electrical Specifications (2/9)

Permissible Pin Injection Current Characteristics in Overvoltage Application ( $\mathrm{T}_{\mathrm{A}}=\mathbf{- 4 0}$ to $+85^{\circ} \mathrm{C}, \mathrm{VDD}=+5 \mathrm{~V}$ $\pm 10 \%$, Vss = 0 V)

| Parameter | Symbol | Condition |  |  | MIN. | TYP. | MAX. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Positive injection current ( $\mathrm{V}_{\mathrm{IN}}>\mathrm{V}$ DD) | lıJH1 | 1 pin | Input ports other than ANn ( $\mathrm{n}=0-7$ ) | Peak value |  |  | 10 | mA |
|  |  |  |  | Mean value |  |  | 0.5 | mA |
|  | liJH2 |  | ANn ( $\mathrm{n}=0-7$ ) | Peak value |  |  | 3 | mA |
|  |  |  |  | Mean value |  |  | 1 | mA |
|  | lish | Total of all input pins |  | Peak value |  |  | 100 | mA |
|  |  |  |  | Mean value |  |  | 5 | mA |
| Negative injection current ( $\mathrm{V}_{\mathrm{IN}}<\mathrm{V}_{\mathrm{ss}}$ ) | IIJL1 | 1 pin | Input ports other than ANn ( $\mathrm{n}=0-7$ ) | Peak value |  |  | -4 | mA |
|  |  |  |  | Mean value |  |  | -0.4 | mA |
|  | IIJL2 |  | ANn ( $\mathrm{n}=0-7$ ) | Peak value |  |  | -4 | mA |
|  |  |  |  | Mean value |  |  | -0.3 | mA |
|  | liJL | Total of all input pins |  | Peak value |  |  | -40 | mA |
|  |  |  |  | Mean value |  |  | -3 | mA |

## Cautions 1. When the injection current has run into the analog input pin (ANn: $\mathbf{n}=0-7$ ), the $A / D$ conversion

 result of the analog input contiguous to the current injection pin has the value of the standard in which the injection current is not running plus $\pm 2$ LSB.2. The mean value (absolute value) of the pin injected current is as follows:

Mean value $=\left(\left.(1 / T) \int_{0}^{T} I i(t)\right|^{3 / 2} d t\right)^{2 / 3}$
In this, $i(t)$ refers to the pin injected current. The maximum value of $\mathrm{li}(\mathrm{t}) \mathrm{I}$ is the peak value.

## Recommended Operating Range

| Oscillation Frequency | $\mathrm{T}_{\mathrm{A}}$ | VDD |
| :---: | :---: | :---: |
| $8 \mathrm{MHz} \leq \mathrm{fxx} \leq 16 \mathrm{MHz}$ | -40 to $+85^{\circ} \mathrm{C}$ | $+5.0 \mathrm{~V} \pm 10 \%$ |

Capacitance $\left(\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}\right.$, Vss $\left.=\mathrm{VdD}=0 \mathrm{~V}\right)$

| Parameter | Symbol | Condition | MIN. | TUP. | MAX. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Input capacitance | $\mathrm{Cl}_{1}$ | $\mathrm{f}=1 \mathrm{MHz} ;$ <br> $0 \vee$ except measured pins |  |  | 10 | pF |
| Output capacitance | Co |  |  |  | 20 | pF |
| I/O capacitance | Cıo |  |  |  | 20 | pF |

(2) $\mu$ PD78P324(A) Electrical Specifications (3/9)

Oscillator Characteristics ( $\mathrm{T}_{\mathrm{A}}=\mathbf{- 4 0}$ to $+85^{\circ} \mathrm{C}, \mathrm{VDD}=+5 \mathrm{~V} \pm 10 \%, \mathrm{Vss}=0 \mathrm{~V}$ )

| Oscillator | Recommended Circuit | Parameter | MIN. | MAX. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Ceramic oscillator or crystal oscillator |  | Oscillation frequency (fxx) | 8 | 16 | MHz |
| External clock | or | X1 input frequency ( fx ) | 8 | 16 | MHz |
|  |  | X1 input rise time, fall time (txr, txf) | 0 | 20 | ns |
|  |  | X1 input high-/low-level width (twxu, twxL) | 25 | 80 | ns |

Caution When using the system clock oscillation circuit, wire the part encircled in the dotted line in the following manner to avoid the influence of the wiring capacity, etc.

- Make the wiring as short as possible.
- Avoid intersecting other signal conductors. Avoid approaching lines in which very high fluctuating currents run.
- Make sure that the grounding point of the oscillation circuit capacitor always has the same electrical potential as Vss. Avoid grounding with a grand pattern in which very high currents run.
- Do not fetch signals from the oscillation circuit.
(2) $\mu$ PD78P324(A) Electrical Specifications (4/9)

DC Characteristics ( $\mathrm{T}_{\mathrm{A}}=\mathbf{- 4 0}$ to $+85^{\circ} \mathrm{C}, \mathrm{VDD}=+\mathbf{5} \mathrm{V} \pm 10 \%, \mathrm{Vss}=\mathbf{0} \mathrm{V}$ )

| Parameter | Symbol | Condition |  | MIN. | TYP. | MAX. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Low-level input voltage | VIL |  |  | 0 |  | 0.8 | V |
| High-level input voltage | $\mathrm{V}_{\mathrm{H} 1}$ | Note 1 |  | 2.2 |  |  | V |
|  | $\mathrm{V}_{\mathbf{H} 2}$ | Note 2 |  | 0.8 VDD |  |  |  |
| Low-level output voltage | Vol | $\mathrm{loL}=2.0 \mathrm{~mA}$ |  |  |  | 0.45 | V |
| High-level output voltage | Voн | $\mathrm{IOH}=-400 \mu \mathrm{~A}$ |  | VDD-1.0 |  |  | V |
| Input leakage current | lL | Note 3 | $0 \mathrm{~V} \leq \mathrm{V}_{1} \leq \mathrm{V}_{\mathrm{DD}}$ |  |  | $\pm 10$ | $\mu \mathrm{A}$ |
| Analog pin input leakage current | Ilian | Note 4 | $0 \mathrm{~V} \leq \mathrm{V}_{\text {IAN }} \leq \mathrm{AV}_{\text {ref }}$ |  |  | $\pm 1$ | $\mu \mathrm{A}$ |
| Output leakage current | Ito | $0 \mathrm{~V} \leq \mathrm{V}_{0} \leq \mathrm{VDD}$ |  |  |  | $\pm 10$ | $\mu \mathrm{A}$ |
| VdD supply current | lod1 | Operation mode |  |  | 70 | 95 | mA |
|  | IdD2 | HALT mode |  |  | 35 | 55 | mA |
| Data retention voltage | Vddor | STOP mode |  | 2.5 |  |  | V |
| Data retention current | Idodr | STOP mode | VDDDR $=2.5 \mathrm{~V}$ |  | 2 | 10 | $\mu \mathrm{A}$ |
|  |  |  | $\mathrm{V}_{\text {Dod }}=5.0 \mathrm{~V} \pm 10 \%$ |  | 10 | 50 | $\mu \mathrm{A}$ |

Notes 1. Pins other than pins in Note 2.
2. $\overline{R E S E T}, \mathrm{X} 1, \mathrm{X} 2, \mathrm{P} 20 / \mathrm{NMI}, \mathrm{P} 21 / I N T P 0, ~ P 22 / I N T P 1, ~ P 23 / I N T P 2, ~ P 24 / I N T P 3, ~ P 25 / I N T P 4, ~ P 26 / I N T P 5, ~ P 27 /$ INTP6/TI, P32/SO/SB0, P33/SI/SB1, P34/SCK pins.
3. Pins except P20/NMI, $\overline{\mathrm{EA}} / \mathrm{VPP}_{\mathrm{P}}, \mathrm{X} 1, \mathrm{X} 2$
4. When not sampling the analog input
(2) $\mu$ PD78P324(A) Electrical Specifications (5/9)

AC Characteristics ( $\mathrm{T}_{\mathrm{A}}=\mathbf{- 4 0}$ to $+85^{\circ} \mathrm{C}, \mathrm{VDD}=+5 \mathrm{~V} \pm 10 \%$, V ss $=0 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=100 \mathrm{pF}$ )
Non-serial Read/Write Operation (when connecting general-purpose memory)

| Parameter | Symbol | Condition | MIN. | MAX. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| System clock cycle time | tçk |  | 125 | 250 | ns |
| Address setup time (vs. ASTB $\downarrow$ ) | tsAST |  | 32 |  | ns |
| Address hold time (vs. ASTB $\downarrow$ ) | thsta |  | 32 |  | ns |
| Address $\rightarrow \overline{\mathrm{RD}} \downarrow$ delay time | toar |  | 85 |  | ns |
| $\overline{\mathrm{RD}} \downarrow \rightarrow$ address float time | tfra |  |  | 10 | ns |
| Address $\rightarrow$ data input time | tDaid |  |  | 222 | ns |
| $\overline{\mathrm{RD}} \downarrow \rightarrow$ data input time | tprid |  |  | 112 | ns |
| ASTB $\downarrow \rightarrow \overline{\mathrm{RD}} \downarrow$ delay time | tostr |  | 42 |  | ns |
| Data hold time (vs. $\overline{\mathrm{RD}} \uparrow$ ) | thrid |  | 0 |  | ns |
| $\overline{\mathrm{RD}} \uparrow \rightarrow$ address active time | tDra |  | 50 |  | ns |
| $\overline{\mathrm{RD}}$ low-level width | twRL |  | 147 |  | ns |
| ASTB high-level width | twsth |  | 37 |  | ns |
| Address $\rightarrow \overline{\mathrm{WR}} \downarrow$ delay time | toaw |  | 85 |  | ns |
| ASTB $\downarrow \rightarrow$ data output time | tostod |  |  | 102 | ns |
| $\overline{\mathrm{WR}} \downarrow \rightarrow$ data output time | towod |  |  | 40 | ns |
| ASTB $\downarrow \rightarrow \overline{\mathrm{WR}} \downarrow$ delay time | tostw |  | 42 |  | ns |
| Data setup time (vs. $\overline{\mathrm{WR}} \uparrow$ ) | tsodw |  | 147 |  | ns |
| Data hold time (vs. $\overline{\mathrm{WR}} \uparrow$ ) | thwod |  | 32 |  | ns |
| $\overline{\mathrm{WR}} \uparrow \rightarrow$ ASTB $\uparrow$ delay time | towst |  | 42 |  | ns |
| $\overline{\mathrm{WR}}$ low-level width | twwL |  | 147 |  | ns |

$\mu$ PD78P324, 78P324(A)
(2) $\mu$ PD78P324(A) Electrical Specifications (6/9)
tсүк-dependent Bus Timing Definition

| Symbol | Calculation formula | MIN./MAX. | Unit |
| :---: | :---: | :---: | :---: |
| tsast | 0.5T-30 | MIN. | ns |
| thsta | 0.5T-30 | MIN. | ns |
| tdar | T-40 | MIN. | ns |
| tDaid | $(2.5+n)$ T-90 | MAX. | ns |
| tbrid | $(1.5+n)$ T-75 | MAX. | ns |
| tostr | 0.5T-20 | MIN. | ns |
| tDra | 0.5T-12 | MIN. | ns |
| tWrL | $(1.5+n)$ T-40 | MIN. | ns |
| twsth | 0.5T-25 | MIN. | ns |
| toaw | T-40 | MIN. | ns |
| tostod | $0.5 \mathrm{~T}+40$ | MAX. | ns |
| tostw | 0.5T-20 | MIN. | ns |
| tsodw | $1.5 \mathrm{~T}-40$ | MIN. | ns |
| thwod | 0.5T-30 | MIN. | ns |
| tDwst | 0.5T-20 | MIN. | ns |
| twwL | $(1.5+n)$ T-40 | MIN. | ns |

Remarks 1. $T=t c y \kappa=1 / f c l \kappa$ (fclk refers to the internal system clock frequency)
2. $n$ refers to the count of weight cycles defined by the user software.
3. Among the parameters for bus timing, only those listed in this table are dependent on tcyk.
(2) $\mu$ PD78P324(A) Electrical Specifications (7/9)

Serial Operation ( $\mathrm{T}_{\mathrm{A}}=-40$ to $+85^{\circ} \mathrm{C}, \mathrm{VDD}=+5 \mathrm{~V} \pm 10 \%$, $\mathrm{Vss}=\mathbf{0} \mathrm{V}$ )

| Parameter | Symbol | Condition |  | MIN. | MAX. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Serial clock cycle time | tCYSK | $\overline{\text { SCK }}$ output | Internal divide-by-eight | 1 |  | $\mu \mathrm{s}$ |
|  |  | $\overline{\text { SCK }}$ input | External clock | 1 |  | $\mu \mathrm{s}$ |
| Serial clock low-level width | tWSKL | $\overline{\text { SCK }}$ output | Internal divide-by-eight | 420 |  | ns |
|  |  | $\overline{\text { SCK }}$ input | External clock | 420 |  | ns |
| Serial clock high-level width | tWSKH | $\overline{\text { SCK }}$ output | Internal divide-by-eight | 420 |  | ns |
|  |  | $\overline{\text { SCK }}$ input | External clock | 420 |  | ns |
| SI setup time (vs. $\overline{\text { SCK }} \uparrow$ ) | tSRXSK |  |  | 80 |  | ns |
| SI hold time (vs. $\overline{\text { SCK }} \uparrow$ ) | tHSKRX |  |  | 80 |  | ns |
| $\overline{\text { SCK }} \downarrow \rightarrow$ SO delay time | tDSKTX | $\mathrm{R}=1 \mathrm{k} \Omega, \mathrm{C}=100 \mathrm{pF}$ |  |  | 210 | ns |

tčк-dependent Serial Operation

| Symbol | Condition |  | Calculation Formula | MIN./MAX. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| tcysk | $\overline{\text { SCK output }}$ | Internal divide-by-eight | 8T | MIN. | ns |
|  | $\overline{\text { SCK }}$ input | External clock | 8T | MIN. | ns |
| twSKL | $\overline{\text { SCK output }}$ | Internal divide-by-eight | 4T-80 | MIN. | ns |
|  | $\overline{\text { SCK }}$ input | External clock | 4T-80 | MIN. | ns |
| twskh | $\overline{\text { SCK }}$ output | Internal divide-by-eight | 4T-80 | MIN. | ns |
|  | $\overline{\text { SCK }}$ input | External clock | 4T-80 | MIN. | ns |

Remarks 1. $T=t \subset y K=1 / f c L k$ (fclk refers to the internal system clock frequency)
2. Among the parameters for serial operation, only those listed in this table are dependent on tcyk.

## (2) $\mu$ PD78P324(A) Electrical Specifications (8/9)

Other Operations ( $\mathrm{T}_{\mathrm{A}}=\mathbf{- 4 0}$ to $+85^{\circ} \mathrm{C}, \mathrm{VDD}=+5 \mathrm{~V} \pm 10 \%, \mathrm{~V}_{\mathrm{DD}}=0 \mathrm{~V}$ )

| Parameter | Symbol | Condition | MIN. | MAX. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| NMI high-/low-level width | twNih, twnil | Analog noises removed | 4 |  | $\mu \mathrm{s}$ |
| INTPO high-/low-level width | twioh, twiol |  | 1 |  | $\mu \mathrm{s}$ |
| INTP1 high-/low-level width | twinh, twinl |  | 1 |  | $\mu \mathrm{s}$ |
| INTP2 high-/low-level width | twi2H, twi2L |  | 1 |  | $\mu \mathrm{s}$ |
| INTP3 high-/low-level width | twi3H, twi3L |  | 1 |  | $\mu \mathrm{s}$ |
| INTP4 high-/low-level width | twi4H, twisk |  | 1 |  | $\mu \mathrm{s}$ |
| INTP5 high-/low-level width | twish, twist |  | 1 |  | $\mu \mathrm{s}$ |
| INTP6 high-/low-level width | twi6H, twi6L |  | 1 |  | $\mu \mathrm{s}$ |
| $\overline{\text { RESET }}$ high-/low-level width | twRSH, twrsL | Analog noises removed | 3.5 |  | $\mu \mathrm{s}$ |
| Tl high-/low-level width | twTIH, twTIL |  | 1 |  | $\mu \mathrm{s}$ |
| VDD rise/fall time | trvo, tfvD |  | 200 |  | $\mu \mathrm{s}$ |

## Other tсүк-dependent Operations

| Symbol | Calculation formula | MIN./MAX. | Unit |
| :---: | :---: | :---: | :---: |
| twioh | 8T | MIN. | ns |
| twiol | 8T | MIN. | ns |
| twin | 8T | MIN. | ns |
| tWI1L | 8T | MIN. | ns |
| twi2H | 8T | MIN. | ns |
| twi2L | 8T | MIN. | ns |
| twi3H | 8T | MIN. | ns |
| twisL | 8T | MIN. | ns |
| twish | 8T | MIN. | ns |
| twi4L | 8T | MIN. | ns |
| twish | 8T | MIN. | ns |
| twisL | 8T | MIN. | ns |
| twi6H | 8T | MIN. | ns |
| twi6L | 8T | MIN. | ns |
| twtir | 8T | MIN. | ns |
| twTIL | 8T | MIN. | ns |

Remarks 1. $\mathrm{T}=\mathrm{tcyk}=1 / \mathrm{fclk}$ (fcLk refers to the internal system clock frequency)
2. Only the parameters listed in this table depend on tcyk.
(2) $\mu$ PD78P324(A) Electrical Specifications (9/9)

AC Timing Test Point



| Parameter | Symbol | Condition |  | MIN. | TYP. | MAX. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Resolution |  |  |  | 10 |  |  | bit |
| Total errorNote 1 |  | $4.5 \mathrm{~V} \leq \mathrm{AV}_{\mathrm{REF}} \leq \mathrm{AV} \mathrm{VdD}$ |  |  |  | $\pm 0.4$ | \%FSR |
|  |  | $3.5 \mathrm{~V} \leq \mathrm{AV}_{\mathrm{REF}} \leq \mathrm{AV} \mathrm{V}_{\mathrm{DD}}$ |  |  |  | $\pm 0.7$ | \%FSR |
| Quantization error |  |  |  |  |  | $\pm 1 / 2$ | LSB |
| Conversion time | tconv |  |  | 144 |  |  | tcyk |
| Sampling time | tsamp |  |  | 24 |  |  | tcyk |
| Zero-scale error ${ }^{\text {Note } 1}$ |  | $4.5 \mathrm{~V} \leq \mathrm{AV}_{\text {ref }} \leq \mathrm{AV}$ do |  |  | $\pm 1.5$ | $\pm 2.5$ | LSB |
|  |  | $3.4 \mathrm{~V} \leq \mathrm{AV}_{\text {ref }} \leq \mathrm{AV}$ do |  |  | $\pm 1.5$ | $\pm 4.5$ | LSB |
| Full-scale error ${ }^{\text {Note } 1}$ |  | $4.5 \mathrm{~V} \leq \mathrm{AV}_{\mathrm{ref}} \leq \mathrm{AV}$ do |  |  | $\pm 1.5$ | $\pm 2.5$ | LSB |
|  |  | $3.4 \mathrm{~V} \leq \mathrm{AV}_{\mathrm{ref}} \leq \mathrm{AV}$ do |  |  | $\pm 1.5$ | $\pm 4.5$ | LSB |
| Non-linear error ${ }^{\text {Note }} 1$ |  | $4.5 \mathrm{~V} \leq \mathrm{AV}_{\text {ref }} \leq \mathrm{AV} \mathrm{V}_{\text {d }}$ |  |  | $\pm 1.5$ | $\pm 2.5$ | LSB |
|  |  | $3.4 \mathrm{~V} \leq \mathrm{AV}_{\mathrm{ref}} \leq \mathrm{AV}_{\text {do }}$ |  |  | $\pm 1.5$ | $\pm 4.5$ | LSB |
| Analog input voltage ${ }^{\text {Note } 2}$ | Vian |  |  | 0 |  | AVdo | V |
| Analog input impedance | Ran | When not sampled |  |  | 10 |  | $\mathrm{M} \Omega$ |
|  |  | When sampled |  |  | Note 3 |  |  |
| Reference voltage | AVref |  |  | 3.4 |  | AVdo | V |
| AVref current | Alref |  |  |  | 1.0 | 3.0 | mA |
| AVdo supply current | Aldo | Operation mode |  |  | 2.0 | 6.0 | mA |
| A/D converter data retention current | Alddor | STOP mode | $\mathrm{AV}_{\text {OOOR }}=2.5 \mathrm{~V}$ |  | 2 | 15 | $\mu \mathrm{A}$ |
|  |  |  |  |  | 10 | 50 | $\mu \mathrm{A}$ |

Notes 1. Quantization error excluded.
2. When Vian $=0 \mathrm{~V}$, the conversion result becomes 000 H .

When $0 \mathrm{~V}<\mathrm{V}_{\text {IAN }}<A V_{\text {REF, }}$ the conversion is performed at a resolution of 10 bits.
When $A V_{\text {ref }} \leq V_{\text {Ian }} \leq A V_{d D}$, the conversion result is 3FFH.
3. The analog input impedance in sampling is the same as the equivalent circuit shown in the diagram below. (The values in the diagram are TYP. values; therefore, they are not assured.)


## (3) $\mu$ PD78P324(A1) Electrical Specifications (1/9)

## Absolute Maximum Ratings ( $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ )

| Parameter | Symbol | Condition |  | Rating | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Supply voltage | VDD |  |  | -0.5 to +7.0 | V |
|  | AVdo |  |  | -0.5 to VDD +0.5 | V |
|  | Vpp |  |  | -0.5 to +13.5 | V |
|  | AVss |  |  | -0.5 to +0.5 | V |
| Input voltage | VI | Notes 1, 2 |  | -0.5 to VDD +0.5 | V |
| Output voltage | Vo |  |  | -0.5 to VDD +0.5 | V |
| Low-level output current | IoL | All output pins |  | 4.0 | mA |
|  |  | Total of all output pins |  | 90 | mA |
| High-level output current | Іон | All output pins |  | -1.0 | mA |
|  |  | Total of all output pins |  | -20 | mA |
| Analog input voltage | Vian | Notes 2, 3 | $A V_{D D}>V_{D D}$ | -0.5 to VDD +0.5 | V |
|  |  |  | VDD $\geq$ AVDD | -0.5 to AVdd +0.5 |  |
| A/D converter reference input voltage | AVref |  | $A V_{D D}>V_{D D}$ | -0.5 to VDD +0.5 | V |
|  |  |  | $V_{D D} \geq$ AV ${ }_{\text {D }}$ | -0.5 to AV DD +0.5 |  |
| Operating ambient temperature | TA |  |  | -40 to +110 | ${ }^{\circ} \mathrm{C}$ |
| Storage temperature | $\mathrm{T}_{\text {stg }}$ |  |  | -65 to +150 | ${ }^{\circ} \mathrm{C}$ |

Notes 1. Except P70/AN0-P77/AN7.
2. The overvoltage condition of the allowable pin injectioncurrent characteristics in overvoltage application is excluded.
3. P70/AN0-P77/AN7 pins.

## Caution If the absolute maximum rating of any one of the parameters is exceeded even momentarily, the

 quality of the product may be degraded. In other words, the product may be physically damaged if any of the absolute maximum ratings is exceeded. Be sure to use the product without exceeding these ratings.(3) $\mu$ PD78P324(A1) Electrical Specifications (2/9)

Permissible Pin Injection Current Characteristics in Overvoltage Application ( $\mathrm{T}_{\mathrm{A}}=\mathbf{- 4 0}$ to $\mathbf{+ 1 1 0}{ }^{\circ} \mathrm{C}, \mathrm{Vdd}=+5 \mathrm{~V}$ $\pm 10 \%$, Vss = 0 V)

| Parameter | Symbol | Condition |  |  | MIN. | TYP. | MAX. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Positive injection current ( $\mathrm{VIN}_{\mathrm{IN}}>\mathrm{V}$ DD $)$ | lıJH1 | 1 pin | Input ports other than ANn ( $\mathrm{n}=0-7$ ) | Peak value |  |  | 10 | mA |
|  |  |  |  | Mean value |  |  | 0.5 | mA |
|  | liJH2 |  | ANn ( $\mathrm{n}=0-7$ ) | Peak value |  |  | 3 | mA |
|  |  |  |  | Mean value |  |  | 1 | mA |
|  | lish | Total of all input pins |  | Peak value |  |  | 100 | mA |
|  |  |  |  | Mean value |  |  | 5 | mA |
| Negative injection current (Vin < Vss) | IIJL1 | 1 pin | Input ports other than ANn ( $\mathrm{n}=0-7$ ) | Peak value |  |  | -4 | mA |
|  |  |  |  | Mean value |  |  | -0.4 | mA |
|  | lıJL2 |  | ANn ( $\mathrm{n}=0-7$ ) | Peak value |  |  | -4 | mA |
|  |  |  |  | Mean value |  |  | -0.3 | mA |
|  | IIJL | Total of all input pins |  | Peak value |  |  | -40 | mA |
|  |  |  |  | Mean value |  |  | -3 | mA |

Cautions 1. When the injection current has run into the analog input pin (ANn: $\mathbf{n}=\mathbf{0 - 7}$ ), the $A / D$ conversion result of the analog input contiguous to the current injection pin has the value of the standard in which the injection current is not running plus $\pm 2$ LSB.
2. The mean value (absolute value) of the pin injected current is as follows:

Mean value $=\left((1 / T) \int_{0}^{T} I i(t) I^{3 / 2} d t\right)^{2 / 3}$
In this, $i(t)$ refers to the pin injected current. The maximum value of $l i(t) I$ is the peak value.

## Recommended Operating Range

| Oscillation Frequency | $T_{A}$ | VDD |
| :---: | :---: | :---: |
| $8 \mathrm{MHz} \leq \mathrm{fxx} \leq 12.5 \mathrm{MHz}$ | -40 to $+110^{\circ} \mathrm{C}$ | $+5.0 \mathrm{~V} \pm 10 \%$ |

Capacitance ( $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{Vss}=\mathrm{VDD}=0 \mathrm{~V}$ )

| Parameter | Symbol | Condition | MIN. | TUP. | MAX. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Input capacitance | $\mathrm{Cl}_{1}$ | $\mathrm{f}=1 \mathrm{MHz} ;$ <br> 0 V except measured pins |  |  | 10 | pF |
| Output capacitance | Co |  |  |  | 20 | pF |
| I/O cpapacitance | Cıo |  |  |  | 20 | pF |

(3) $\mu$ PD78P324(A1) Electrical Specifications (3/9)

Oscillator Characteristics ( $\mathrm{T}_{\mathrm{A}}=\mathbf{- 4 0}$ to $+110{ }^{\circ} \mathrm{C}, \mathrm{VdD}=+5 \mathrm{~V} \pm 10 \%, \mathrm{Vss}=0 \mathrm{~V}$ )

| Oscillator | Recommended Circuit | Parameter | MIN. | MAX. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Ceramic oscillator or crystal oscillator |  | Oscillation frequency ( $\mathrm{fxx}^{\text {) }}$ | 8 | 12.5 | MHz |
| External clock | or $\begin{array}{\|ll\|} \mathrm{X} 1 & \mathrm{X} 2 \\ \hline \end{array}$ | X1 input frequency ( fx ) | 8 | 12.5 | MHz |
|  | No connection requiredHCMOS inverter | X1 input rise time, fall time (txr, txf) | 0 | 20 | ns |
|  |  | X1 input high-/low-level width (twxe, twxı) | 46 | 100 | ns |

Caution When using the system clock oscillation circuit, wire the part encircled in the dotted line in the following manner to avoid the influence of the wiring capacity, etc.

- Make the wiring as short as possible.
- Avoid intersecting other signal conductors. Avoid approaching lines in which very high fluctuating currents run.
- Make sure that the grounding point of the oscillation circuit capacitor always has the same electrical potential as Vss. Avoid grounding with a grand pattern in which very high currents run.
- Do not fetch signals from the oscillation circuit.
(3) $\mu$ PD78P324(A1) Electrical Specifications (4/9)

DC Characteristics ( $\mathrm{T}_{\mathrm{A}}=\mathbf{- 4 0}$ to $+110^{\circ} \mathrm{C}, \mathrm{VdD}=+5 \mathrm{~V} \pm 10 \%, \mathrm{Vss}=0 \mathrm{~V}$ )

| Parameter | Symbol | Condition |  |  | MIN. | TYP. | MAX. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Low-level input voltage | VIL |  |  |  | 0 |  | 0.8 | V |
| High-level input voltage | $\mathrm{V}_{1+1}$ | Note 1 |  |  | 2.2 |  |  | V |
|  | $\mathrm{V}_{1+2}$ | Note 2 |  |  | 0.8 VDD |  |  |  |
| Low-level output voltage | Vol | $\mathrm{loL}=2.0 \mathrm{~mA}$ |  |  |  |  | 0.45 | V |
| High-level output voltage | Vон | I он $=-400 \mu \mathrm{~A}$ |  |  | VDD-1.0 |  |  | V |
| Input leakage current | ILI | Note 3 |  | $\mathrm{V} \leq \mathrm{V}_{\mathrm{I}} \leq \mathrm{V}_{\mathrm{DD}}$ |  |  | $\pm 10$ | $\mu \mathrm{A}$ |
| Analog pin input leakage current | ILIAN | Note 4 |  | $\mathrm{V} \leq \mathrm{V}_{\text {IAN }} \leq \mathrm{A} \mathrm{V}_{\text {ref }}$ |  |  | $\pm 2$ | $\mu \mathrm{A}$ |
| Output leakage current | ILo | $0 \mathrm{~V} \leq \mathrm{V}_{0} \leq \mathrm{V}_{\mathrm{DD}}$ |  |  |  |  | $\pm 10$ | $\mu \mathrm{A}$ |
| Vod supply current | IdD1 | Operation mode |  |  |  | 65 | 87 | mA |
|  | IdD2 | HALT mode |  |  |  | 25 | 48 | mA |
| Data retention voltage | Vdddr | STOP mode |  |  | 2.5 |  |  | V |
| Data retention current | Iddor | STOP mode |  | $V_{\text {dDD }}=2.5 \mathrm{~V}$ |  | 2 | 100 | $\mu \mathrm{A}$ |
|  |  |  |  | VDDDR=5.0 $\mathrm{V} \pm 10 \%$ |  | 10 | 1000 | $\mu \mathrm{A}$ |

Notes 1. Pins other than pins in Note 2.
2. RESET, X1, X2, P20/NMI, P21/INTP0, P22/INTP1, P23/INTP2, P24/INTP3, P25/INTP4, P26/INTP5, P27/ INTP6/TI, P32/SO/SB0, P33/SI/SB1, P34/SCK pins.
3. Pins except P20/NMI, EA/Vpp, X1, X2
4. When not sampling the analog input

## (3) $\mu$ PD78P324(A1) Electrical Specifications (5/9)

$A C$ Characteristics ( $\mathrm{T}_{\mathrm{A}}=-40$ to $+110^{\circ} \mathrm{C}, \mathrm{VDD}=+5 \mathrm{~V} \pm 10 \%$, $\mathrm{Vss}=0 \mathrm{~V}, \mathrm{C}_{\mathrm{L}}=100 \mathrm{pF}$ )
Non-serial Read/Write Operation (when connecting general-purpose memory)

| Parameter | Symbol | Condition | MIN. | MAX. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| System clock cycle time | tcyk |  | 160 | 250 | ns |
| Address setup time (vs. ASTB $\downarrow$ ) | tsAST |  | 40 |  | ns |
| Address hold time (vs. ASTB $\downarrow$ ) | thsta |  | 50 |  | ns |
| Address $\rightarrow \overline{\mathrm{RD}} \downarrow$ delay time | tdar |  | 120 |  | ns |
| $\overline{\mathrm{RD}} \downarrow \rightarrow$ address float time | tfra |  |  | 10 | ns |
| Address $\rightarrow$ data input time | toaid |  |  | 310 | ns |
| $\overline{\mathrm{RD}} \downarrow \rightarrow$ data input time | tDRID |  |  | 165 | ns |
| ASTB $\downarrow \rightarrow \overline{\mathrm{RD}} \downarrow$ delay time | tostr |  | 60 |  | ns |
| Data hold time (vs. $\overline{\mathrm{RD}} \uparrow$ ) | thrid |  | 0 |  | ns |
| $\overline{\mathrm{RD}} \uparrow \rightarrow$ address active time | tDra |  | 68 |  | ns |
| $\overline{\mathrm{RD}}$ low-level width | twrL |  | 191 |  | ns |
| ASTB high-level width | twsth |  | 55 |  | ns |
| Address $\rightarrow \overline{\mathrm{WR}} \downarrow$ delay time | toaw |  | 120 |  | ns |
| ASTB $\downarrow \rightarrow$ data output time | tbstod |  |  | 120 | ns |
| $\overline{\mathrm{WR}} \downarrow \rightarrow$ data output time | towod |  |  | 40 | ns |
| ASTB $\downarrow \rightarrow \overline{\mathrm{WR}} \downarrow$ delay time | tdstw |  | 60 |  | ns |
| Data setup time (vs. $\overline{\mathrm{WR}} \uparrow$ ) | tsodw |  | 191 |  | ns |
| Data hold time (vs. $\overline{\mathrm{WR}} \uparrow$ ) | thwod |  | 50 |  | ns |
| $\overline{\mathrm{WR}} \uparrow \rightarrow$ ASTB $\uparrow$ delay time | towst |  | 60 |  | ns |
| $\overline{\mathrm{WR}}$ low-level width | twwL |  | 195 |  | ns |

(3) $\mu$ PD78P324(A1) Electrical Specifications (6/9)
tcyk-dependent Bus Timing Definition

| Symbol | Calculation formula | MIN./MAX. | Unit |
| :---: | :---: | :---: | :---: |
| tSAST | 0.5T-40 | MIN. | ns |
| thsta | 0.5T-30 | MIN. | ns |
| tDar | T-40 | MIN. | ns |
| tDaid | $(2.5+n)$ T-90 | MAX. | ns |
| tdrid | $(1.5+n)$ T-75 | MAX. | ns |
| tostr | 0.5T-20 | MIN. | ns |
| tDRA | 0.5T-12 | MIN. | ns |
| twrL | $(1.5+n)$ T-49 | MIN. | ns |
| twsth | 0.5T-25 | MIN. | ns |
| toaw | T-40 | MIN. | ns |
| tostod | $0.5 \mathrm{~T}+40$ | MAX. | ns |
| tostw | 0.5T-20 | MIN. | ns |
| tsodw | 1.5T-49 | MIN. | ns |
| thwod | 0.5T-30 | MIN. | ns |
| towst | 0.5T-20 | MIN. | ns |
| twwL | $(1.5+n)$ T-45 | MIN. | ns |

Remarks 1. $T=t$ tcyk $=1 /$ fclk (fclk refers to the internal system clock frequency)
2. $n$ refers to the count of weight cycles defined by the user software.
3. Among the parameters for bus timing, only those listed in this table are dependent on tcyk.
(3) $\mu$ PD78P324(A1) Electrical Specifications (7/9)

Serial Operation ( $\mathrm{T}_{\mathrm{A}}=\mathbf{- 4 0}$ to $+110^{\circ} \mathrm{C}, \mathrm{VDD}=+5 \mathrm{~V} \pm 10 \%, \mathrm{Vss}=0 \mathrm{~V}$ )

| Parameter | Symbol | Condition |  | MIN. | MAX. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Serial clock cycle time | tcysk | $\overline{\text { SCK }}$ output | Internal divide-by-eight | 1280 |  | $\mu \mathrm{s}$ |
|  |  | $\overline{\text { SCK }}$ input | External clock | 1280 |  | $\mu \mathrm{s}$ |
| Serial clock low-level width | twSKL | $\overline{\text { SCK output }}$ | Internal divide-by-eight | 560 |  | ns |
|  |  | $\overline{\text { SCK }}$ input | External clock | 560 |  | ns |
| Serial clock high-level width | twSKH | $\overline{\text { SCK output }}$ | Internal divide-by-eight | 560 |  | ns |
|  |  | $\overline{\text { SCK }}$ input | External clock | 560 |  | ns |
| SI setup time (vs. $\overline{\text { SCK }} \uparrow$ ) | tsrxsk |  |  | 80 |  | ns |
| SI hold time (vs. $\overline{\text { SCK }} \uparrow$ ) | thSKRX |  |  | 80 |  | ns |
| $\overline{\text { SCK }} \downarrow \rightarrow$ SO delay time | tDSkTX | $\mathrm{R}=1 \mathrm{k} \Omega, \mathrm{C}=10$ |  |  | 210 | ns |

tcyк-dependent Serial Operation

| Symbol | Condition |  | Calculation Formula | MIN./MAX. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| tcysk | $\overline{\text { SCK }}$ output | Internal divide-by-eight | 8T | MIN. | ns |
|  | $\overline{\text { SCK }}$ input | External clock | 8T | MIN. | ns |
| twskL | $\overline{\text { SCK }}$ output | Internal divide-by-eight | 4T-80 | MIN. | ns |
|  | $\overline{\text { SCK }}$ input | External clock | 4T-80 | MIN. | ns |
| twskh | $\overline{\text { SCK }}$ output | Internal divide-by-eight | 4T-80 | MIN. | ns |
|  | $\overline{\text { SCK }}$ input | External clock | 4T-80 | MIN. | ns |

Remarks 1. $T=t c y k=1 / f c L K$ (fcLk refers to the internal system clock frequency)
2. Among the parameters for serial operation, only those listed in this table are dependent on tcyk.

## (3) $\mu$ PD78P324(A1) Electrical Specifications (8/9)

Other Operations ( $\mathrm{T}_{\mathrm{A}}=-40$ to $\left.+110^{\circ} \mathrm{C}, \mathrm{VDD}=+5 \mathrm{~V} \pm 10 \%, \mathrm{~V}_{\mathrm{DD}}=\mathbf{0} \mathrm{V}\right)$

| Parameter | Symbol | Condition | MIN. | MAX. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| NMI high-/low-level width | twnim, twnil | Analog noises removed | 4 |  | $\mu \mathrm{s}$ |
| INTP0 high-/low-level width | twioh, twiol |  | 1280 |  | ns |
| INTP1 high-/low-level width | twi1h, twi1L |  | 1280 |  | ns |
| INTP2 high-/low-level width | twi2H, twi2L |  | 1280 |  | ns |
| INTP3 high-/low-level width | twi3\%, twi3L |  | 1280 |  | ns |
| INTP4 high-/low-level width | twi4h, twisk |  | 1280 |  | ns |
| INTP5 high-/low-level width | twish, twisk |  | 1280 |  | ns |
| INTP6 high-/low-level width | twi6\%, twi6L |  | 1280 |  | ns |
| $\overline{\text { RESET }}$ high-/low-level width | twrsh, twrsL | Analog noises removed | 3.5 |  | $\mu \mathrm{s}$ |
| TI high-/low-level width | twTil, twill |  | 1280 |  | ns |
| Vdd rise/fall time | trvo, tfvd |  | 200 |  | $\mu \mathrm{s}$ |

Other tcүк-dependent Operations

| Symbol | Calculation formula | MIN./MAX. | Unit |
| :---: | :---: | :---: | :---: |
| twioh | 8T | MIN. | ns |
| twiol | 8T | MIN. | ns |
| twin | 8T | MIN. | ns |
| twill | 8T | MIN. | ns |
| twi2H | 8T | MIN. | ns |
| twi2L | 8T | MIN. | ns |
| twi3H | 8T | MIN. | ns |
| twi3L | 8T | MIN. | ns |
| twish | 8T | MIN. | ns |
| tWI4L | 8 T | MIN. | ns |
| twish | 8T | MIN. | ns |
| twisL | 8T | MIN. | ns |
| twi6H | 8T | MIN. | ns |
| twi6L | 8T | MIN. | ns |
| twTiH | 8T | MIN. | ns |
| twTIL | 8T | MIN. | ns |

Remarks 1. $\mathrm{T}=\mathrm{t}$ tcyk $=1 /$ fclk (fclk refers to the internal system clock frequency)
2. Only the parameters listed in this table depend on tсүк.

## (3) $\mu$ PD78P324(A1) Electrical Specifications (9/9)

## AC Timing Test Point



A/D Converter Characteristics ( $\mathrm{T}_{\mathrm{A}}=\mathbf{- 4 0}$ to $+110^{\circ} \mathrm{C}, \mathrm{VdD}=+5 \mathrm{~V} \pm 10 \%$, $\mathrm{V}_{\mathrm{ss}}=\mathrm{AV}$ ss $=\mathbf{0} \mathrm{V}, \mathrm{VDD}-\mathbf{0 . 5} \mathrm{V} \leq \mathrm{AVDD} \leq \mathrm{V}_{\mathrm{DD}}$ )

| Parameter | Symbol | Condition |  | MIN. | TYP. | MAX | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Resolution |  |  |  | 10 |  |  | bit |
| Total error ${ }^{\text {Note }} 1$ |  | $4.5 \mathrm{~V} \leq \mathrm{AV}_{\text {REF }} \leq \mathrm{AV} \mathrm{DD}$ |  |  |  | $\pm 0.4$ | \%FSR |
|  |  | $3.5 \mathrm{~V} \leq \mathrm{AV}_{\mathrm{REF}} \leq \mathrm{AV} \mathrm{Vd}$ |  |  |  | $\pm 0.7$ | \%FSR |
| Quantization error |  |  |  |  |  | $\pm 1 / 2$ | LSB |
| Conversion time | tconv |  |  | 144 |  |  | tcyk |
| Sampling time | tsamp |  |  | 24 |  |  | tcyk |
| Zero-scale error ${ }^{\text {Note } 1}$ |  | $4.5 \mathrm{~V} \leq \mathrm{AV}_{\mathrm{REF}} \leq \mathrm{AV} \mathrm{VDD}$ |  |  | $\pm 1.5$ | $\pm 2.5$ | LSB |
|  |  | $3.4 \mathrm{~V} \leq \mathrm{AV}_{\mathrm{REF}} \leq \mathrm{AV} \mathrm{VDD}$ |  |  | $\pm 1.5$ | $\pm 4.5$ | LSB |
| Full-scale error ${ }^{\text {Note } 1}$ |  | $4.5 \mathrm{~V} \leq \mathrm{AV}_{\mathrm{REF}} \leq \mathrm{AV} \mathrm{VdD}$ |  |  | $\pm 1.5$ | $\pm 2.5$ | LSB |
|  |  | $3.4 \mathrm{~V} \leq \mathrm{AV}_{\text {REF }} \leq \mathrm{AV} \mathrm{VD}$ |  |  | $\pm 1.5$ | $\pm 4.5$ | LSB |
| Non-linear error ${ }^{\text {Note } 1}$ |  | $4.5 \mathrm{~V} \leq \mathrm{AV}_{\mathrm{REF}} \leq \mathrm{AV} \mathrm{DD}$ |  |  | $\pm 1.5$ | $\pm 2.5$ | LSB |
|  |  | $3.4 \mathrm{~V} \leq \mathrm{AV}_{\mathrm{REF}} \leq \mathrm{AV}$ dD |  |  | $\pm 1.5$ | $\pm 4.5$ | LSB |
| Analog input voltage ${ }^{\text {Note } 2}$ | VIAN |  |  | 0 |  | AVDD | V |
| Analog input impedance | Ran | When not sampled |  |  | 10 |  | $\mathrm{M} \Omega$ |
|  |  | When sampled |  |  | Note 3 |  |  |
| Reference voltage | AVref |  |  | 3.4 |  | AVdD | V |
| A $\mathrm{V}_{\text {ref }}$ current | Alref |  |  |  | 1.0 | 3.0 | mA |
| AVDD supply current | Aldd | Operation mode |  |  | 2.0 | 6.0 | mA |
| A/D converter data retention current | Alddor | STOP mode | AV DDDR $=2.5 \mathrm{~V}$ |  | 2 | 100 | $\mu \mathrm{A}$ |
|  |  |  | AV DDDR $5 \mathrm{~V} \pm 10 \%$ |  | 10 | 1000 | $\mu \mathrm{A}$ |

Notes 1. Quantization error excluded.
2. When Vian $=0 \mathrm{~V}$, the conversion result becomes 000 H .

When $0 \mathrm{~V}<\mathrm{V}_{\text {Ian }}<A V_{\text {ref, }}$ the conversion is performed at a resolution of 10 bits.
When $A V_{\text {ref }} \leq V_{\text {Ian }} \leq A V d d$, the conversion result is 3FFH.
3. The analog input impedance in sampling is the same as the equivalent circuit shown in the diagram below. (The values in the diagram are TYP. values; therefore, they are not assured.)

(4) $\mu$ PD78P324(A2) Electrical Specifications (1/9)

Absolute Maximum Ratings ( $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$ )

| Parameter | Symbol | Condition |  | Rating | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Supply voltage | Vdo |  |  | -0.5 to +7.0 | V |
|  | AVdD |  |  | -0.5 to VDD +0.5 | V |
|  | Vpp |  |  | -0.5 to +13.5 | V |
|  | AVss |  |  | -0.5 to +0.5 | V |
| Input voltage | VI | Notes 1, 2 |  | -0.5 to VDD +0.5 | V |
| Output voltage | Vo |  |  | -0.5 to VdD +0.5 | V |
| Low-level output current | IoL | All output pins |  | 4.0 | mA |
|  |  | Total of all output pins |  | 90 | mA |
| High-level output current | Іон | All output pins |  | -1.0 | mA |
|  |  | Total of all output pins |  | -20 | mA |
| Analog input voltage | Vian | Notes 2, 3 | $A V_{D D}>V_{D D}$ | -0.5 to VDD +0.5 | V |
|  |  |  | $V_{D D} \geq$ AV ${ }_{\text {dD }}$ | -0.5 to AVDD +0.5 |  |
| A/D converter reference input voltage | AVref |  | $A V_{D D}>V_{\text {dD }}$ | -0.5 to VDD +0.5 | V |
|  |  |  | $V_{D D} \geq \mathrm{AV}_{\text {dD }}$ | -0.5 to AVDD +0.5 |  |
| Operating ambient temperature | TA |  |  | -40 to +125 | ${ }^{\circ} \mathrm{C}$ |
| Storage temperature | Tstg |  |  | -65 to +150 | ${ }^{\circ} \mathrm{C}$ |

Notes 1. Except P70/AN0-P77/AN7.
2. The overvoltage condition of the allowable pin injectioncurrent characteristics in overvoltage application is excluded.
3. P70/AN0-P77/AN7 pins.

Caution If the absolute maximum rating of any one of the parameters is exceeded even momentarily, the quality of the product may be degraded. In other words, the product may be physically damaged if any of the absolute maximum ratings is exceeded. Be sure to use the product without exceeding these ratings.
(4) $\mu$ PD78P324(A2) Electrical Specifications (2/9)

Permissible Pin Injection Current Characteristics in Overvoltage Application ( $\mathrm{T}_{\mathrm{A}}=\mathbf{- 4 0}$ to $+\mathbf{1 2 5}{ }^{\circ} \mathrm{C}, \mathrm{VdD}=+5 \mathrm{~V}$ $\pm 10 \%$, Vss = 0 V)

| Parameter | Symbol | Condition |  |  | MIN. | TYP. | MAX. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Positive injection current ( $\mathrm{V}_{\mathrm{IN}}>\mathrm{V}$ DD) | lıJH1 | 1 pin | Input ports other than ANn ( $\mathrm{n}=0-7$ ) | Peak value |  |  | 10 | mA |
|  |  |  |  | Mean value |  |  | 0.5 | mA |
|  | liJH2 |  | ANn ( $\mathrm{n}=0-7$ ) | Peak value |  |  | 3 | mA |
|  |  |  |  | Mean value |  |  | 1 | mA |
|  | lish | Total of all input pins |  | Peak value |  |  | 100 | mA |
|  |  |  |  | Mean value |  |  | 5 | mA |
| Negative injection current ( $\mathrm{V}_{\mathrm{IN}}<\mathrm{V}_{\mathrm{ss}}$ ) | IIJL1 | 1 pin | Input ports other than ANn ( $\mathrm{n}=0-7$ ) | Peak value |  |  | -4 | mA |
|  |  |  |  | Mean value |  |  | -0.4 | mA |
|  | IIJL2 |  | ANn ( $\mathrm{n}=0-7$ ) | Peak value |  |  | -4 | mA |
|  |  |  |  | Mean value |  |  | -0.3 | mA |
|  | liJL | Total of all input pins |  | Peak value |  |  | -40 | mA |
|  |  |  |  | Mean value |  |  | -3 | mA |

Cautions. 1. When the injection current has run into the analog input pin (ANn: $\mathbf{n}=0-7$ ), the $A / D$ conversion result of the analog input contiguous to the current injection pin has the value of the standard in which the injection current is not running plus $\pm 2$ LSB.
2. The mean value (absolute value) of the pin injected current is as follows:

Mean value $=\left(\left.(1 / T) \int_{0}^{T} I i(t)\right|^{3 / 2} d t\right)^{2 / 3}$
In this, $i(t)$ refers to the pin injected current. The maximum value of $\mathrm{li}(\mathrm{t}) \mathrm{I}$ is the peak value.

## Recommended Operating Range

| Oscillation Frequency | $\mathrm{T}_{\mathrm{A}}$ | VDD |
| :---: | :---: | :---: |
| $8 \mathrm{MHz} \leq \mathrm{fxx} \leq 12.5 \mathrm{MHz}$ | -40 to $+125^{\circ} \mathrm{C}$ | $+5.0 \mathrm{~V} \pm 10 \%$ |

Capacitance $\left(\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{ss}}=\mathrm{V}_{\mathrm{DD}}=0 \mathrm{~V}\right)$

| Parameter | Symbol | Condition | MIN. | TUP. | MAX. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Input capacitance | $\mathrm{Cl}_{1}$ | $\mathrm{f}=1 \mathrm{MHz} ;$ <br> $0 \vee$ except measured pins |  |  | 10 | pF |
| Output capacitance | Co |  |  |  | 20 | pF |
| I/O capacitance | Cıo |  |  |  | 20 | pF |

(4) $\mu$ PD78P324(A2) Electrical Specifications (3/9)

Oscillator Characteristics ( $\mathrm{T}_{\mathrm{A}}=40$ to $+125^{\circ} \mathrm{C}, \mathrm{VDD}=+5 \mathrm{~V} \pm 10 \%, \mathrm{Vss}=\mathbf{0} \mathrm{V}$ )

| Oscillator | Recommended Circuit | Parameter | MIN. | MAX. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Ceramic oscillator or crystal oscillator |  | Oscillation frequency (fxx) | 8 | 12.5 | MHz |
| External clock | or | X1 input frequency ( fx ) | 8 | 12.5 | MHz |
|  |  | X1 input rise time, fall time (txr, txf) | 0 | 20 | ns |
|  |  | X1 input high-/low-level width (twxh, twxL) | 46 | 100 | ns |

Caution When using the system clock oscillation circuit, wire the part encircled in the dotted line in the following manner to avoid the influence of the wiring capacity, etc.

- Make the wiring as short as possible.
- Avoid intersecting other signal conductors. Avoid approaching lines in which very high fluctuating currents run.
- Make sure that the grounding point of the oscillation circuit capacitor always has the same electrical potential as Vss. Avoid grounding with a grand pattern in which very high currents run.
- Do not fetch signals from the oscillation circuit.
(4) $\mu$ PD78P324(A2) Electrical Specifications (4/9)

DC Characteristics ( $\mathrm{T}_{\mathrm{A}}=\mathbf{- 4 0}$ to $+125^{\circ} \mathrm{C}, \mathrm{VDD}=+5 \mathrm{~V} \pm 10 \%, \mathrm{Vss}=0 \mathrm{~V}$ )

| Parameter | Symbol | Condition |  |  | MIN. | TYP. | MAX. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Low-level input voltage | VIL |  |  |  | 0 |  | 0.8 | V |
| High-level input voltage | VIH1 | Note 1 |  |  | 2.2 |  |  | V |
|  | $\mathrm{V}_{\mathrm{H} 2}$ | Note 2 |  |  | 0.8 VDD |  |  |  |
| Low-level output voltage | Vol | $\mathrm{loL}=2.0 \mathrm{~mA}$ |  |  |  |  | 0.45 | V |
| High-level output voltage | Vон | I он $=-400 \mu \mathrm{~A}$ |  |  | VdD-1.0 |  |  | V |
| Input leakage current | lLI | Note 3 |  | $\mathrm{V} \leq \mathrm{V}_{1} \leq \mathrm{V}_{\mathrm{DD}}$ |  |  | $\pm 10$ | $\mu \mathrm{A}$ |
| Analog pin input leakage current | Ilian | Note 4 |  | $\mathrm{V} \leq \mathrm{V}_{\text {Ian }} \leq \mathrm{A} \mathrm{V}_{\text {ref }}$ |  |  | $\pm 2$ | $\mu \mathrm{A}$ |
| Output leakage current | ILo | $0 \mathrm{~V} \leq \mathrm{V}_{0} \leq \mathrm{V}_{\mathrm{DD}}$ |  |  |  |  | $\pm 10$ | $\mu \mathrm{A}$ |
| Vod supply current | IdD1 | Operation mode |  |  |  | 65 | 87 | mA |
|  | IdD2 | HALT mode |  |  |  | 25 | 48 | mA |
| Data retention voltage | Vdddr | STOP mode |  |  | 2.5 |  |  | V |
| Data retention current | Iddor | STOP mode |  | $\mathrm{V}_{\text {ddDr }}=2.5 \mathrm{~V}$ |  | 2 | 100 | $\mu \mathrm{A}$ |
|  |  |  |  | VDDDR=5.0 $\mathrm{V} \pm 10 \%$ |  | 10 | 1000 | $\mu \mathrm{A}$ |

Notes 1. Pins other than pins in Note 2.
2. $\overline{R E S E T}, \mathrm{X} 1, \mathrm{X} 2, \mathrm{P} 20 / \mathrm{NMI}, \mathrm{P} 21 / I N T P 0, ~ P 22 / I N T P 1, ~ P 23 / I N T P 2, ~ P 24 / I N T P 3, ~ P 25 / I N T P 4, ~ P 26 / I N T P 5, ~ P 27 /$ INTP6/TI, P32/SO/SB0, P33/SI/SB1, P34/SCK pins.
3. Pins except P20/NMI, $\overline{\mathrm{EA}} / \mathrm{VPP}_{\mathrm{P}}, \mathrm{X} 1, \mathrm{X} 2$
4. When not sampling the analog input

## (4) $\mu$ PD78P324(A2) Electrical Specifications (5/9)

AC Characteristics ( $\mathrm{T}_{\mathrm{A}}=\mathbf{- 4 0}$ to $+125{ }^{\circ} \mathrm{C}, \mathrm{VDD}=+5 \mathrm{~V} \pm 10 \%$, $\mathrm{Vss}=\mathbf{0} \mathrm{V}, \mathrm{C}_{\mathrm{L}}=100 \mathrm{pF}$ )
Non-serial Read/Write Operation (when connecting general-purpose memory)

| Parameter | Symbol | Condition | MIN. | MAX. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| System clock cycle time | tçk |  | 160 | 250 | ns |
| Address setup time (vs. ASTB $\downarrow$ ) | tsAST |  | 40 |  | ns |
| Address hold time (vs. ASTB $\downarrow$ ) | thsta |  | 50 |  | ns |
| Address $\rightarrow \overline{\mathrm{RD}} \downarrow$ delay time | toar |  | 120 |  | ns |
| $\overline{\mathrm{RD}} \downarrow \rightarrow$ address float time | tfra |  |  | 10 | ns |
| Address $\rightarrow$ data input time | tDaid |  |  | 310 | ns |
| $\overline{\mathrm{RD}} \downarrow \rightarrow$ data input time | tprid |  |  | 165 | ns |
| ASTB $\downarrow \rightarrow \overline{\mathrm{RD}} \downarrow$ delay time | tostr |  | 60 |  | ns |
| Data hold time (vs. $\overline{\mathrm{RD}} \uparrow$ ) | thrid |  | 0 |  | ns |
| $\overline{\mathrm{RD}} \uparrow \rightarrow$ address active time | tDra |  | 68 |  | ns |
| $\overline{\mathrm{RD}}$ low-level width | twRL |  | 191 |  | ns |
| ASTB high-level width | twsth |  | 55 |  | ns |
| Address $\rightarrow \overline{\mathrm{WR}} \downarrow$ delay time | toaw |  | 120 |  | ns |
| ASTB $\downarrow \rightarrow$ data output time | tostod |  |  | 120 | ns |
| $\overline{\mathrm{WR}} \downarrow \rightarrow$ data output time | towod |  |  | 40 | ns |
| ASTB $\downarrow \rightarrow \overline{\mathrm{WR}} \downarrow$ delay time | tostw |  | 60 |  | ns |
| Data setup time (vs. $\overline{\mathrm{WR}} \uparrow$ ) | tsodw |  | 191 |  | ns |
| Data hold time (vs. $\overline{\mathrm{WR}} \uparrow$ ) | thwod |  | 50 |  | ns |
| $\overline{\mathrm{WR}} \uparrow \rightarrow$ ASTB $\uparrow$ delay time | towst |  | 60 |  | ns |
| $\overline{\mathrm{WR}}$ low-level width | twwL |  | 195 |  | ns |

$\mu$ PD78P324, 78P324(A)
(4) $\mu$ PD78P324(A2) Electrical Specifications (6/9)
tсүк-dependent Bus Timing Definition

| Symbol | Calculation formula | MIN./MAX. | Unit |
| :---: | :---: | :---: | :---: |
| tsast | 0.5T-40 | MIN. | ns |
| thsta | 0.5T-30 | MIN. | ns |
| tDar | T-40 | MIN. | ns |
| tDaid | $(2.5+n)$ T-90 | MAX. | ns |
| tDRID | $(1.5+n)$ T-75 | MAX. | ns |
| tostr | 0.5T-20 | MIN. | ns |
| tDRA | 0.5T-12 | MIN. | ns |
| twrL | $(1.5+n)$ T-49 | MIN. | ns |
| twsth | 0.5T-25 | MIN. | ns |
| toaw | T-40 | MIN. | ns |
| tostod | $0.5 \mathrm{~T}+40$ | MAX. | ns |
| tostw | 0.5T-20 | MIN. | ns |
| tsodw | 1.5T-49 | MIN. | ns |
| thwod | 0.5T-30 | MIN. | ns |
| towst | 0.5T-20 | MIN. | ns |
| twwL | $(1.5+n)$ T-45 | MIN. | ns |

Remarks 1. $T=t c y \kappa=1 / f c l \kappa$ (fclk refers to the internal system clock frequency)
2. $n$ refers to the count of weight cycles defined by the user software.
3. Among the parameters for bus timing, only those listed in this table are dependent on tcyk.
(4) $\mu$ PD78P324(A2) Electrical Specifications (7/9)

Serial Operation ( $\mathrm{T}_{\mathrm{A}}=\mathbf{4 0}$ to $+125^{\circ} \mathrm{C}, \mathrm{VDD}=+5 \mathrm{~V} \pm 10 \%, \mathrm{Vss}=0 \mathrm{~V}$ )

| Parameter | Symbol | Condition |  | MIN. | MAX. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Serial clock cycle time | tCYSK | $\overline{\text { SCK }}$ output | Internal divide-by-eight | 1280 |  | $\mu \mathrm{s}$ |
|  |  | $\overline{\text { SCK }}$ input | External clock | 1280 |  | $\mu \mathrm{s}$ |
| Serial clock low-level width | tWSKL | $\overline{\text { SCK }}$ output | Internal divide-by-eight | 560 |  | ns |
|  |  | $\overline{\text { SCK }}$ input | External clock | 560 |  | ns |
| Serial clock high-level width | tWSKH | $\overline{\text { SCK }}$ output | Internal divide-by-eight | 560 |  | ns |
|  |  | $\overline{\text { SCK }}$ input | External clock | 560 |  | ns |
| SI setup time (vs. $\overline{\text { SCK }} \uparrow$ ) | tSRXSK |  |  | 80 |  | ns |
| SI hold time (vs. $\overline{\text { SCK }} \uparrow$ ) | tHSKRX |  |  | 80 |  | ns |
| $\overline{\text { SCK }} \downarrow \rightarrow$ SO delay time | tDSKTX | $\mathrm{R}=1 \mathrm{k} \Omega, \mathrm{C}=100 \mathrm{pF}$ |  |  | 210 | ns |

tčк-dependent Serial Operation

| Symbol | Condition |  | Calculation Formula | MIN./MAX. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| tcysk | $\overline{\text { SCK }}$ output | Internal divide-by-eight | 8T | MIN. | ns |
|  | $\overline{\text { SCK }}$ input | External clock | 8T | MIN. | ns |
| twSKL | $\overline{\text { SCK output }}$ | Internal divide-by-eight | 4T-80 | MIN. | ns |
|  | $\overline{\text { SCK }}$ input | External clock | 4T-80 | MIN. | ns |
| twskh | $\overline{\text { SCK output }}$ | Internal divide-by-eight | 4T-80 | MIN. | ns |
|  | $\overline{\text { SCK }}$ input | External clock | 4T-80 | MIN. | ns |

Remarks 1. $\mathrm{T}=\mathrm{t}$ tсYк $=1 / \mathrm{fcLK}$ (fcLk refers to the internal system clock frequency)
2. Among the parameters for serial operation, only those listed in this table are dependent on tcyk.

## (4) $\mu$ PD78P324(A2) Electrical Specifications (8/9)

Other Operations ( $\mathrm{T}_{\mathrm{A}}=\mathbf{- 4 0}$ to $+125^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{DD}}=+5 \mathrm{~V} \pm 10 \%, \mathrm{~V}_{\mathrm{dD}}=\mathbf{0} \mathrm{V}$ )

| Parameter | Symbol | Condition | MIN. | MAX. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| NMI high-/low-level width | twnim, twNiL | Analog noises removed | 4 |  | $\mu \mathrm{s}$ |
| INTPO high-/low-level width | twioh, twiol |  | 1280 |  | ns |
| INTP1 high-/low-level width | twi1h, twill |  | 1280 |  | ns |
| INTP2 high-/low-level width | twi2h, twi2L |  | 1280 |  | ns |
| INTP3 high-/low-level width | twi3h, twi3L |  | 1280 |  | ns |
| INTP4 high-/low-level width | twi4h, twi4L |  | 1280 |  | ns |
| INTP5 high-/low-level width | twish, twisk |  | 1280 |  | ns |
| INTP6 high-/low-level width | twi6H, twi6L |  | 1280 |  | ns |
| $\overline{\text { RESET }}$ high-/low-level width | twrsh, twrsL | Analog noises removed | 3.5 |  | $\mu \mathrm{s}$ |
| Tl high-/low-level width | twTIH, twTlL |  | 1280 |  | ns |
| Vdd rise/fall time | trvo, tfvD |  | 200 |  | $\mu \mathrm{s}$ |

## Other tсүк-dependent Operations

| Symbol | Calculation formula | MIN./MAX. | Unit |
| :---: | :---: | :---: | :---: |
| twioh | 8T | MIN. | ns |
| twiol | 8T | MIN. | ns |
| twin | 8T | MIN. | ns |
| twill | 8T | MIN. | ns |
| twi2H | 8T | MIN. | ns |
| twi2L | 8T | MIN. | ns |
| twi3H | 8T | MIN. | ns |
| twi3L | 8T | MIN. | ns |
| twish | 8T | MIN. | ns |
| twi4L | 8T | MIN. | ns |
| twish | 8T | MIN. | ns |
| twisL | 8T | MIN. | ns |
| twi6H | 8T | MIN. | ns |
| twi6L | 8T | MIN. | ns |
| twtir | 8T | MIN. | ns |
| twTIL | 8T | MIN. | ns |

Remarks 1. $\mathrm{T}=\mathrm{tcyk}=1 / \mathrm{fclk}$ (fcLk refers to the internal system clock frequency)
2. Only the parameters listed in this table depend on tсук.

## (4) $\mu$ PD78P324(A2) Electrical Specifications (9/9)

## AC Timing Test Point



A/D Converter Characteristics ( $\mathrm{T}_{\mathrm{A}}=\mathbf{- 4 0}$ to $+125^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{DD}}=+5 \mathrm{~V} \pm 10 \%, \mathrm{~V}_{\mathrm{ss}}=\mathrm{AV}$ ss $=\mathbf{0} \mathrm{V}, \mathrm{V}_{\mathrm{DD}} \mathbf{- 0 . 5} \mathrm{V} \leq \mathrm{AV} \mathrm{DD} \leq \mathrm{V}_{\mathrm{DD}}$ )

| Parameter | Symbol | Condition |  | MIN. | TYP. | MAX. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Resolution |  |  |  | 10 |  |  | bit |
| Total errorNote 1 |  | $4.5 \mathrm{~V} \leq \mathrm{AV}_{\text {REF }} \leq \mathrm{AV}_{\text {dD }}$ |  |  |  | $\pm 0.4$ | \%FSR |
|  |  | $3.5 \mathrm{~V} \leq \mathrm{AV}_{\mathrm{REF}} \leq \mathrm{AV} \mathrm{V}_{\mathrm{DD}}$ |  |  |  | $\pm 0.7$ | \%FSR |
| Quantization error |  |  |  |  |  | $\pm 1 / 2$ | LSB |
| Conversion time | tconv |  |  | 144 |  |  | tcyk |
| Sampling time | tsamp |  |  | 24 |  |  | tcyk |
| Zero-scale error ${ }^{\text {Note } 1}$ |  | $4.5 \mathrm{~V} \leq \mathrm{AV}_{\text {ref }} \leq \mathrm{AV}$ do |  |  | $\pm 1.5$ | $\pm 2.5$ | LSB |
|  |  | $3.4 \mathrm{~V} \leq \mathrm{AV}_{\text {ref }} \leq \mathrm{AV}$ do |  |  | $\pm 1.5$ | $\pm 4.5$ | LSB |
| Full-scale error ${ }^{\text {Note } 1}$ |  | $4.5 \mathrm{~V} \leq \mathrm{AV}_{\mathrm{ref}} \leq \mathrm{AV}$ do |  |  | $\pm 1.5$ | $\pm 2.5$ | LSB |
|  |  | $3.4 \mathrm{~V} \leq \mathrm{AV}_{\mathrm{ref}} \leq \mathrm{AV}$ do |  |  | $\pm 1.5$ | $\pm 4.5$ | LSB |
| Non-linear error ${ }^{\text {Note }} 1$ |  | $4.5 \mathrm{~V} \leq \mathrm{AV}_{\text {ref }} \leq \mathrm{AV} \mathrm{V}_{\text {d }}$ |  |  | $\pm 1.5$ | $\pm 2.5$ | LSB |
|  |  | $3.4 \mathrm{~V} \leq \mathrm{AV}_{\mathrm{ref}} \leq \mathrm{AV}_{\text {do }}$ |  |  | $\pm 1.5$ | $\pm 4.5$ | LSB |
| Analog input voltage ${ }^{\text {Note } 2}$ | Vian |  |  | 0 |  | AVdd | V |
| Analog input impedance | Ran | When not sampled |  |  | 10 |  | $\mathrm{M} \Omega$ |
|  |  | When sampled |  |  | Note 3 |  |  |
| Reference voltage | AVref |  |  | 3.4 |  | AVdd | V |
| AVref current | Alref |  |  |  | 1.0 | 3.0 | mA |
| AVdo supply current | Aldo | Operation mode |  |  | 2.0 | 6.0 | mA |
| A/D converter data retention current | Alddor | STOP mode | $\mathrm{AV}_{\text {OOOR }}=2.5 \mathrm{~V}$ |  | 2 | 100 | $\mu \mathrm{A}$ |
|  |  |  |  |  | 10 | 1000 | $\mu \mathrm{A}$ |

Notes 1. Quantization error excluded.
2. When Vian $=0 \mathrm{~V}$, the conversion result becomes 000 H .

When $0 \mathrm{~V}<\mathrm{V}_{\text {IAN }}<A V_{\text {ref, }}$ the conversion is performed at a resolution of 10 bits.
When $A V_{\text {ref }} \leq V_{\text {Ian }} \leq A V_{d D}$, the conversion result is 3FFH.
3. The analog input impedance in sampling is the same as the equivalent circuit shown in the diagram below. (The values in the diagram are TYP. values; therefore, they are not assured.)


## Non-serial Read Operation



## Non-serial Write Operation



Serial Operation


Interrupt Input Timing


Remark $n=0-6$

## Reset Input Timing



TI Pin Input Timing


Data Retention Timing


DC Programming Characteristics ( $\mathrm{T}_{\mathrm{A}}=25 \pm 5^{\circ} \mathrm{C}, \mathrm{V}$ ss $=0 \mathrm{~V}$ )

| Parameter | Symbol | Symbol ${ }^{\text {Note } 1}$ | Condition | MIN. | TYP. | MAX. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| High-level input voltage | $\mathrm{V}_{\mathrm{H}}$ | $\mathrm{V}_{\mathrm{H}}$ |  | 2.4 |  | VdDP+0.3 | V |
| Low-level input voltage | VIL | VIL |  | -0.3 |  | 0.8 | V |
| Input leakage current | ILI | ILI | $0 \leq \mathrm{V}_{1} \leq \mathrm{V}_{\text {dop }}{ }^{\text {Note }}$ 2 |  |  | $\pm 10$ | $\mu \mathrm{A}$ |
| High-level output voltage | Vон | Vон | Іон $=-400 \mu \mathrm{~A}$ | 2.4 |  |  | V |
| Low-level output voltage | VoL | VoL | $\mathrm{loL}=2.0 \mu \mathrm{~A}$ |  |  | 0.45 | V |
| Input current | IA9 | - | A9(P20/NMI) pin, $0 \leq \mathrm{V}_{0} \leq \mathrm{V}_{\text {dop }}$ |  |  | $\pm 10$ | $\mu \mathrm{A}$ |
| Output leakage current | Ito | - | $0 \leq \mathrm{V}_{\mathrm{O}} \leq \mathrm{V}_{\text {dop }}, \overline{\mathrm{OE}}=\mathrm{V}_{\mathrm{IH}}$ |  |  | $\pm 10$ | $\mu \mathrm{A}$ |
| Vodp supply voltage | VDDP | Vcc | Program memory Write mode | 6.25 | 65 | 6.75 | V |
|  |  |  | Program memory Read mode | 4.5 | 5.0 | 5.5 | V |
| VPP supply voltage | Vpp | Vpp | Program memory Write mode | 12.2 | 12.5 | 12.8 | V |
|  |  |  | Program memory Read mode | $V_{\text {PP }}=\mathrm{V}_{\text {DDP }}$ |  |  | V |
| Vodp supply current | IDD | IDD | Program memory Write mode |  |  | 30 | mA |
|  |  |  | Program memory Read mode |  |  | 50 | mA |
| VPP supply current | IPp | IPP | Program memory Write mode $\overline{\mathrm{CE}}=\overline{\mathrm{PGM}}$ |  |  | 50 | mA |
|  |  |  | Program memory Read mode $V_{P P}=V_{D D}$ |  | 1 | 100 | $\mu \mathrm{A}$ |

Notes 1. Refers to the symbol of the corresponding $\mu$ PD27C1001A.
2. Vddp refers to the Vdd pin in programming.

AC Programming Characteristics ( $\mathrm{T}_{\mathrm{A}}=25 \pm \mathrm{E}^{\circ} \mathrm{C}, \mathrm{V} \mathrm{Ss}=0 \mathrm{~V}$ )

In PROM Write Mode

| Parameter | Symbol ${ }^{\text {Note1 }}$ | Condition | MIN. | TYP. | MAX. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Address setup time | $\mathrm{tas}^{\text {S }}$ |  | 2 |  |  | $\mu \mathrm{s}$ |
| $\overline{\mathrm{CE}}$ set time | tces |  | 2 |  |  | $\mu \mathrm{s}$ |
| Input data setup time | tbs |  | 2 |  |  | $\mu \mathrm{s}$ |
| Address hold time | $\mathrm{taH}^{\text {H }}$ |  | 2 |  |  | $\mu \mathrm{s}$ |
| Input data hold time | ton |  | 2 |  |  | $\mu \mathrm{s}$ |
| Output data hold time | tbF |  | 0 |  | 130 | ns |
| VPP setup time | tvps |  | 2 |  |  | $\mu \mathrm{s}$ |
| Vodp setup time | tvos ${ }^{\text {Note }} 2$ |  | 2 |  |  | $\mu \mathrm{s}$ |
| Initial program pulse width | tpw |  | 0.095 | 0.1 | 0.105 | ms |
| $\overline{\mathrm{OE}}$ set time | toes |  | 2 |  |  | $\mu \mathrm{s}$ |
| $\overline{\mathrm{OE}} \rightarrow$ valid data delay time | toe |  |  |  | 200 | ns |

Notes 1. Corresponds to the symbol of $\mu$ PD27C1001A (tvos excluded).
2. The symbol of tvds on $\mu$ PD27C1001A is tvcs.

## In PROM Read Mode

| Parameter | Symbol ${ }^{\text {Note1 }}$ | Condition | MIN. | TYP. | MAX. | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Address $\rightarrow$ data output time | tacc | $\overline{\mathrm{CE}}=\overline{\mathrm{OE}}=\mathrm{V}_{\mathrm{IL}}$ |  |  | 2 | $\mu \mathrm{s}$ |
| $\overline{\mathrm{CE}} \downarrow \rightarrow$ data output time | tce | $\overline{\mathrm{OE}}=\mathrm{V}_{\mathrm{IL}}$ |  |  | 1 | $\mu \mathrm{s}$ |
| $\overline{\mathrm{OE}} \downarrow \rightarrow$ data output time | toe | $\overline{\mathrm{CE}}=\mathrm{V}_{\text {IL }}$ |  |  | 1 | $\mu \mathrm{s}$ |
| Data hold time (vs. $\overline{\mathrm{OE}} \uparrow, \overline{\mathrm{CE}} \uparrow$ ) ${ }^{\text {Note } 2}$ | tbF | $\overline{\mathrm{CE}}=\mathrm{V}_{\text {IL }}$ or $\overline{O E}=\mathrm{V}_{\text {IL }}$ | 0 |  | 130 | ns |
| Data hold time (vs. address) | toh | $\overline{\mathrm{CE}}=\overline{\mathrm{OE}}=\mathrm{V}_{\mathrm{IL}}$ | 0 |  |  | ns |

Notes 1. Corresponds to the symbol of $\mu$ PD27C1001A.
2. tdF refers to the time when either $\overline{\mathrm{OE}}$ or $\overline{\mathrm{CE}}$ became $\mathrm{V}_{\mathrm{IH}}$ first.

PROM Write Mode Timing


## Cautions 1. Ensure to apply VdDP before Vpp, and disconnect it after Vpp.

2. Ensure that Vpp does not exceed +13.5 V even when the overshoot is included.
3. Taking out or putting in while +12.5 V is applied to VPP may cause adverse effects on the reliability.

## PROM Read Mode Timing



Notes 1. To read within the range of tacc, please make sure that the delay time from CE's falling edge of the OE input is up to tacc-toe.
2. tdF refers to the time when either $\overline{\mathrm{OE}}$ or $\overline{\mathrm{CE}}$ became $\mathrm{V}_{\mathrm{IH}}$ first.

## 8. PACKAGE DRAWINGS

74-Pin Plastic QFP( $\square$ 20)


## NOTE

Each lead centerline is located within 0.20 mm ( 0.008 inch ) of its true position (T.P.) at maximum material condition.

Remark The package and material of the ES product are equivalent to those for mass production.
detail of lead end


| ITEM | MILLIMETERS | INCHES |
| :---: | :---: | :---: |
| A | $23.2 \pm 0.4$ | $0.913_{-0.016}^{+0.017}$ |
| B | $20.0 \pm 0.2$ | $0.787_{-0.008}^{+0.009}$ |
| C | $20.0 \pm 0.2$ | $0.787_{-0.008}^{+0.009}$ |
| D | $23.2 \pm 0.4$ | $0.913_{-0.016}^{+0.017}$ |
| $\mathrm{F}_{1}$ | 2.0 | 0.079 |
| F2 | 1.0 | 0.039 |
| G1 | 2.0 | 0.079 |
| G2 | 1.0 | 0.039 |
| H | $0.40 \pm 0.10$ | $0.016_{-0.005}^{+0.004}$ |
| 1 | 0.20 | 0.008 |
| $J$ | 1.0 (T.P.) | 0.039 (T.P.) |
| K | $1.6 \pm 0.2$ | $0.063 \pm 0.008$ |
| L | $0.8 \pm 0.2$ | $0.031_{-0.008}^{+0.009}$ |
| M | $0.15_{-0.05}^{+0.10}$ | $0.006_{-0.003}^{+0.004}$ |
| N | 0.10 | 0.004 |
| P | 3.7 | 0.146 |
| Q | $0.1 \pm 0.1$ | $0.004 \pm 0.004$ |
| R | $5^{\circ} \pm 5^{\circ}$ | $5^{\circ} \pm 5^{\circ}$ |
| S | 4.0 MAX. | 0.158 MAX. |
|  |  | 574GJ-100-5BJ-3 |

## 68 PIN PLASTIC OFJ ( $\square 950$ mil)



P68L-50A1-2

## NOTE

Each lead centerline is located within 0.12 mm ( 0.005 inch) of its true position (T.P.) at maximum material condition.

Remark The package and material of the ES product are equivalent to those formass production.

| ITEM | MILLIMETERS | INCHES |
| :--- | :--- | :--- |
| A | $25.2 \pm 0.2$ | $0.992 \pm 0.008$ |
| B | 24.20 | 0.953 |
| C | 24.20 | 0.953 |
| D | $25.2 \pm 0.2$ | $0.992 \pm 0.008$ |
| E | $1.94 \pm 0.15$ | $0.076_{-0.006}^{+0.007}$ |
| F | 0.6 | 0.024 |
| G | $4.4 \pm 0.2$ | $0.173_{-0.008}^{+0.009}$ |
| H | $2.8 \pm 0.2$ | $0.110_{-0.008}^{+0.009}$ |
| I | 0.9 MIN. | 0.035 MIN. |
| J | 3.4 | 0.134 |
| K | 1.27 (T.P.) | 0.050 (T.P.) |
| M | $0.40 \pm 1.0$ | $0.016_{-0.005}^{+0.004}$ |
| N | 0.12 | 0.005 |
| P | $23.12 \pm 0.20$ | $0.910_{-0.008}^{+0.009}$ |
| Q | 0.15 | 0.006 |
| T | R 0.8 | $R$ |
| U | $0.20_{-0.05}^{+0.10}$ | $0.008_{-0.002}^{+0.004}$ |

## 74 PIN CERAMIC WOFN



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## NOTE

Each lead centerline is located within 0.10 mm ( 0.004 inch) of its true position (T.P.) at maximum material condition.

Remark The package and material of the ES product are equivalent to those for mass production.

| ITEM |  | MILLIMETERS |
| :---: | :--- | :--- |
| A | $20.0 \pm 0.4$ | INCHES |
| B | 18.0 | $0.787_{-0.016}^{+0.017}$ |
| C | 18.0 | 0.709 |
| D | $20.0 \pm 0.4$ | 0.709 |
| E | 1.94 | $0.787_{-0.016}^{+0.017}$ |
| F | 2.14 | 0.076 |
| G | 4.0 MAX | 0.084 |
| H | $0.51 \pm 0.10$ | 0.158 MAX. |
| I | 0.10 | $0.020 \pm 0.004$ |
| J | 1.0 (T.P.) | 0.004 |
| K | $1.0 \pm 0.2$ | 0.039 (T.P.) |
| Q | C 0.3 | $0.039_{-0.008}^{+0.009}$ |
| R | 2.0 | C 0.012 |
| S | 2.0 | 0.079 |
| T | R 2.0 | 0.079 |
| U | 10.0 | R 0.079 |
| W | $0.7 \pm 0.2$ | 0.394 |
| Y | C 1.5 | $0.028_{-0.009}^{+0.008}$ |
| C 0.059 |  |  |

## 68 PIN CERAMIC WOFN


note
Each lead centerline is located within 0.12 mm ( 0.005 inch) of its true position (T.P.) at maximum material condition.

Remark The package and material of the ES product are equivalent to those for mass production.

X68KW-50A-1

| ITEM | MILLIMETERS | INCHES |
| :--- | :--- | :--- |
| A | $24.13 \pm 0.4$ | $0.950 \pm 0.016$ |
| B | 21.5 | 0.846 |
| C | 21.5 | 0.846 |
| D | $24.13 \pm 0.4$ | $0.950 \pm 0.016$ |
| E | 1.65 | 0.065 |
| F | 2.03 | 0.080 |
| G | 3.50 MAX. | 0.138 MAX. |
| H | $0.64 \pm 0.10$ | $0.025_{-0.004}^{+0.005}$ |
| I | 0.12 | 0.005 |
| J | 1.27 (T.P.) | 0.05 (T.P.) |
| K | $1.27 \pm 0.2$ | $0.05 \pm 0.008$ |
| L | $2.16 \pm 0.2$ | $0.085 \pm 0.008$ |
| P | R 0.2 | R 0.008 |
| Q | C 1.02 | C 0.04 |
| R | 1.905 | 0.075 |
| S | 1.905 | 0.075 |
| T | R 3.0 | R 0.118 |
| U | 12.0 | 0.472 |
| Y | C 0.5 | C 0.020 |
| P |  |  |

## 9. RECOMMENDED SOLDERING CONDITIONS

Please solder the package of this product under the conditions recommended as follows.
For details of the recommended conditions for soldering, please refer to the information document "Semiconductor Device Mounting Technology Manual" (IEI-1207).

For soldering methods and conditions other than those recommended below, please contact NEC sales personnel.

Table 9-1. Soldering Conditions for Surface-Mount Type (1)

| $\mu$ PD78P324GJ-5BJ | $:$ 74-pin plastic QFP (20 x 20 mm$)$ |
| :--- | :--- |
| $\mu$ PD78P324LP | $:$ 68-pin plastic QFJ $(\square 950 \mathrm{mil})$ |
| $\mu$ PD78P324LP(A) | $:$ 68-pin plastic QFJ $(\square 950 \mathrm{mil})$ |
| $\mu$ PD78P324LP(A1) | $:$ 68-pin plastic QFJ $(\square 950 \mathrm{mil})$ |
| $\mu$ PD78P324LP(A2) | $:$ 68-pin plastic QFJ $(\square 950 \mathrm{mil})$ |


| Soldering Method | Soldering Condition | Recommended Condition Symbol |
| :---: | :---: | :---: |
| Infrared reflow | Package peak temperature : $230^{\circ} \mathrm{C}$; time : within 30 secs ( $210^{\circ} \mathrm{C}$ or more); count: once; day limit : 7 days ${ }^{\text {Note }}$ (hereafter, pre-baked for 36 hrs at $125^{\circ} \mathrm{C}$ ) | IR30-367-1 |
| VPS | Package peak temperature : $215^{\circ} \mathrm{C}$; time : within 40 secs ( $200^{\circ} \mathrm{C}$ or more); count: once; day limit : 7 days ${ }^{\text {Note }}$ (hereafter, pre-baked for 36 hrs at $125^{\circ} \mathrm{C}$ ) | VP15-367-1 |
| Wave soldering | Solder bath temperature: no more than $260^{\circ} \mathrm{C}$; time : within 10 secs; count: once; preheating temperature : $120^{\circ} \mathrm{C}$ max. (package surface temperature); day limit : 7 days $^{\text {Note }}$ (hereafter, pre-baked for 36 hours at $125^{\circ} \mathrm{C}$ ) | WS60-367-1 |
| Pin part heating | Pin temperature : no more than $300{ }^{\circ} \mathrm{C}$; time : within 3 secs (per device side) | - |

Note Refers to the number of days for storage after the dry pack is opened. The storage conditions are $25^{\circ} \mathrm{C}$ and no more than $65 \%$ RH.

Caution Avoid using multiple soldering methods at the same time (except the pin part heating method).

Table 9-2. Soldering Conditions for Surface-Mount Type (2)

| $\mu$ PD78P324GJ(A)-5BJ | $:$ 74-pin plastic QFP $(20 \times 20 \mathrm{~mm})$ |
| :--- | :--- |
| $\mu$ PD78P324GJ(A1)-5BJ | $:$ 74-pin plastic QFP $(20 \times 20 \mathrm{~mm})$ |
| $\mu$ PD78P324GJ(A2)-5BJ | $: 74-$ pin plastic QFP $(20 \times 20 \mathrm{~mm})$ |


| Soldering Method | Soldering Condition | Recommended Condition Symbol |
| :---: | :---: | :---: |
| Infrared reflow | Package peak temperature: $235^{\circ} \mathrm{C}$; time: within 30 secs ( $210^{\circ} \mathrm{C}$ or more) ; count: twice; day limit: 7 days ${ }^{\text {Note }}$ (hereafter, pre-baked for 36 hrs at $125^{\circ} \mathrm{C}$ ) <Caution> <br> (1) The second reflow should be started after the temperature of the device which would have been changed by the first reflow has returned to normal. <br> (2) Please avoid flux water washing after the first reflow. | IR35-367-2 |
| VPS | Package peak temperature: $215^{\circ} \mathrm{C}$; time: within 40 secs ( $200^{\circ} \mathrm{C}$ or more) ; count: within twice; day limit: 7 days ${ }^{\text {Note }}$ (hereafter, pre-baked for 36 hrs at $125^{\circ} \mathrm{C}$ ) <br> <Caution> <br> (1) The second reflow should be started after the temperature of the device which would have been changed by the first reflow has returned to normal. <br> (2) Please avoid flux water washing after the first reflow. | VP15-367-2 |
| Wave soldering | Solder bath temperature: no more than $260^{\circ} \mathrm{C}$; time: within 10 secs; count: once; preheating temperature: up to $120^{\circ} \mathrm{C}$ (package surface temperature); day limit: 7 days ${ }^{\text {Note }}$ (hereafter, pre-baked for 36 hours at $125^{\circ} \mathrm{C}$ ) | WS60-367-1 |
| Pin part heating | Pin temperature: no more than $300^{\circ} \mathrm{C}$; time: within 3 secs (per device side) | - |

Note Refers to the number of days for storage after the dry pack is opened. The storage conditions are $25^{\circ} \mathrm{C}$ and no more than $65 \%$ RH.

## Caution Avoid using two or more soldering methods at the same time (except the pin part heating method).

## APPENDIX A. CONVERSION SOCKET PACKAGE DRAWING AND RECOMMENDED SUBSTRATE INSTALLATION PATTERN

Figure A-1. Conversion Socket (EV-9200G-74) Package Drawing (Reference)


| ITEM | MILLIMETERS | EV-9200G-74-G0 |
| :---: | :--- | :--- |
| A | 25.0 | 0.984 |
| B | 20.35 | 0.801 |
| C | 20.35 | 0.801 |
| D | 25.0 | 0.984 |
| E | $4-C 2.8$ | $4-C \quad 0.11$ |
| F | 1.0 | 0.039 |
| G | 11.0 | 0.433 |
| H | 22.0 | 0.866 |
| I | 24.7 | 0.972 |
| J | 5.0 | 0.197 |
| K | 22.0 | 0.866 |
| L | 24.7 | 0.972 |
| M | 8.0 | 0.315 |
| N | 7.8 | 0.307 |
| O | 2.5 | 0.098 |
| P | 2.0 | 0.079 |
| Q | 1.35 | 0.053 |
| R | $0.35 \pm 0.1$ | $0.014_{-0.0005}^{+0.004}$ |
| S | $\phi 2.3$ | $\phi 0.091$ |
| T | $\phi 1.5$ | 0.059 |
|  |  |  |

Figure A-2. Recommended Pattern for Conversion Socket (EV-9200G-74) Substrate Installation (Reference)


| EV-9200G-74-PO |  |  |
| :---: | :---: | :---: |
| ITEM | MILLIMETERS | INCHES |
| A | 25.7 | 1.012 |
| B | 21.0 | 0.827 |
| C | $1.0 \pm 0.02 \times 18=18.0 \pm 0.05$ | $0.039_{-0.000}^{+0.002} \times 0.709=0.709_{-0.003}^{+0.002}$ |
| D | $1.0 \pm 0.02 \times 18=18.0 \pm 0.05$ | $0.039_{-0.001}^{+0.002} \times 0.709=0.709_{-0.003}^{+0.002}$ |
| E | 21.0 | 0.827 |
| F | 25.7 | 1.012 |
| G | $11.00 \pm 0.08$ | $0.433_{-0.003}^{+0.004}$ |
| H | $5.00 \pm 0.08$ | $0.197_{-0.004}^{+0.003}$ |
| I | $0.6 \pm 0.02$ | $0.024_{-0.001}^{+0.002}$ |
| J | $\phi 2.36 \pm 0.03$ | $\phi 0.093_{-0.001}^{+0.001}$ |
| K | $\phi 1.57 \pm 0.03$ | $\phi 0.062_{-0.002}^{+0.001}$ |

Caution Dimensions of mount pad for EV-9200 and that for target device (QFP) may be different in some parts. For the recommended mount pad dimensions for QFP, refer to "SEMICONDUCTOR DEVICE MOUNTING TECHNOLOGY MANUAL" (IEI-1207).

## APPENDIX B. TOOLS

## B. 1 DEVELOPMENT TOOLS

The following development tools have been made available for development of the system using the $\mu$ PD78P324.

## Language Processors

| 78K/III series relocatable assembler (RA78K/III) | Refers to the relocatable assembler which can be used commonly for the 78K/III series. Equipped with the macro function, the relocatable assembler is aimed at improved development efficiency. The assembler is also accompanied by the structured assembler which can describe the program control structure explicitly, thus making it possible to improve the productivity and the maintainability of the program. |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
|  | Host machine |  |  | Part number |
|  |  | OS | Supply medium |  |
|  | PC-9800 series | MS-DOS ${ }^{\text {™ }}$ | 3.5-inch 2HD | $\mu$ S5A13RA78K3 |
|  |  |  | 5-inch 2HD | $\mu$ S5A10RA78K3 |
|  | IBM PC/AT ${ }^{\text {TM }}$ and its compatible machine | PC DOS ${ }^{\text {TM }}$ | 3.5-inch 2HC | $\mu$ S7B13RA78K3 |
|  |  |  | 5-inch 2HC | $\mu$ S7B10RA78K3 |
|  | HP9000 series 300 ${ }^{\text {TM }}$ | HP-UX ${ }^{\text {™ }}$ | Cartridge tape (OIC-24) | $\mu \mathrm{S} 3 \mathrm{H} 15 \mathrm{RA} 48 \mathrm{~K} 3$ |
|  | SPARCstation ${ }^{\text {TM }}$ | SunOS ${ }^{\text {TM }}$ |  | $\mu \mathrm{S} 3 \mathrm{~K} 15 \mathrm{RA} 78 \mathrm{~K} 3$ |
| 78K/III series C compiler (CC78K/III) | Refers to the C compiler which can be commonly used in the $78 \mathrm{~K} / \mathrm{III}$ series. This compiler is a program converting the programs written in the C language to those object codes which are executable by microcomputers. When using this compiler, the $78 \mathrm{~K} / \mathrm{III}$ series relocatable assembler (RA78K/III) is required. |  |  |  |
|  | Host machine | , |  | Part number |
|  |  | OS | Supply medium |  |
|  | PC-9800 series | MS-DOS | 3.5-inch 2HD | $\mu$ S5A13CC78K3 |
|  |  |  | 5-inch 2HD | $\mu$ S5A10CC78K3 |
|  | IBM PC/AT and its compatible machine | PC DOS | 3.5-inch 2 HC | $\mu$ S7B13CC78K3 |
|  |  |  | 5-inch 2HC | $\mu$ S7B10CC78K3 |
|  | HP9000 series 300 | HP-UX | Cartridge tape (OIC-24) | $\mu \mathrm{S3H} 15 \mathrm{CC} 78 \mathrm{~K} 3$ |
|  | SPARCstation | SunOS |  | $\mu \mathrm{S} 3 \mathrm{~K} 15 \mathrm{CC} 78 \mathrm{~K} 3$ |

Remark Relocatable assembler and C compiler operations are assured only on the host machine and the OS above.

## PROM Write Tools

| Hardware | PG-1500 | This PROM programmer is capable of programming by manipulating a PROMincorporated single-chip microcomputer from a stand-alone or host machine after connecting the accompanying board and the separately available programmer adapter. <br> It can also program representative PROMs ranging from 256 Kbits to 4 Mbits. |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | $\begin{aligned} & \text { UNISITE } \\ & 2900 \\ & 3900^{\text {Note }} \end{aligned}$ | These are PROM programmers made by Data I/O Japan. |  |  |  |
|  | PA-78P324GJ <br> PA-78P324LP <br> PA-78P324KC <br> PA-78P324KD | These are the PROM programmer adapters for writing programs into the $\mu$ PD78P324 on general-purpose PROM programmer such as PG-1500. <br> PA-78P324GJ: for $\mu$ PD78P324GJ <br> PA-78P324LP: for $\mu$ PD78P324LP <br> PA-78P324KC: for $\mu$ PD78P324KC <br> PA-78P324KD: for $\mu$ PD78P324KD |  |  |  |
| Software | PG-1500 controller | A PG-1500 and a host machine are connected with the serial interface or the parallel interface to control the PG-1500 on the host machine. |  |  |  |
|  |  | Host machine | OS | Supply medium | Part number |
|  |  | PC-9800 series | MS-DOS | 3.5-inch 2HD | $\mu$ S5A13PG1500 |
|  |  |  |  | 5-inch 2HD | $\mu$ S5A10PG1500 |
|  |  | IBM PC/AT and its compatible machine | PC DOS | 3.5-inch 2 HC | $\mu$ S7B13PG1500 |
|  |  |  |  | 5-inch 2HC | $\mu$ S7B10PG1500 |

Note Being evaluated.

Remark The PG-1500 controller operation is assured only on the host machine and the OS above.

## Debugging Tools

| Hardware | IE-78327-R <br> IE-78320-R Note <br> EP-78320GJ-R <br> EP-78320L-R | These are the in-circuit emulators which can be used for the development and debugging of application systems. Debugging is performed by connecting them to a host machine. The IE-78327-R can be used commonly for both the $\mu$ PD78322 subseries and the $\mu$ PD78328 subseries. <br> The IE-78320-R can be used for the $\mu$ PD78322 subseries. |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | These are the emulation probes for connecting the IE-78327-R or IE-78320-R to a target system. <br> EP-78320GJ-R: for 74-pin plastic QFP <br> EP-78320L-R: for 68-pin plastic QFJ |  |  |  |
|  | IE-78327-R control program (IE controller) | This program is for controlling the IE-78327-R from a host machine. It can execute commands automatically, thus enabling more efficient debugging. |  |  |  |
|  |  | Host machine | OS | Supply medium | Part number |
|  |  | PC-9800 series | MS-DOS | 3.5-inch 2HD | $\mu$ S5A13IE78327 |
|  |  |  |  | 5-inch 2HD | $\mu$ S5A10IE78327 |
|  |  | IBM PC/AT and its compatible machine | PC DOS | 3.5-inch 2HC | $\mu$ S7B13IE78327 |
|  |  |  |  | 5-inch 2HC | $\mu$ S7B10IE78327 |
| Software | IE-78320-R control program ${ }^{\text {Note }}$ (IE controller) | This program is for controlling the IE-78320-R from a host machine. It can execute commands automatically, thus enabling more efficient debugging. |  |  |  |
|  |  | Host machine |  |  | Part number |
|  |  |  | OS | Supply medium |  |
|  |  | PC-9800 series | MS-DOS | 3.5-inch 2HD | $\mu$ S5A13IE78320 |
|  |  |  |  | 5-inch 2HD | $\mu$ S5A10IE78320 |
|  |  | IBM PC/AT and its compatible machine | PC DOS | 5-inch 2HC | $\mu$ S7B10IE78320 |

Remarks 1. The operation of each software is assured only on the host machine and the OS above.
2. $\mu$ PD78322 subseries: $\mu$ PD78320, 78322, 78P322, 78323, 78324, 78P324, 78320(A), 78320(A1), 78320(A2), 78322(A), 78322(A1), 78322(A2), 78323(A), 78323(A1), 78323(A2),
78324(A), 78324(A1), 78324(A2), 78P324(A), 78P324(A1), 78P324(A2)
$\mu$ PD78328 subseries: $\quad \mu$ PD78327, 78328, 78P328, 78327(A), 78328(A)
Note The existing product IE-78320-R is a maintenance product. If you are going to newly purchase an in-circuit emulator, please use the alternative product IE-78327-R.

## Development Tool Configurations



Note The socket is supplied with the emulation probe.

Remarks 1. It is also possible to use the host machine and the PG-1500 by connecting them directly by the RS-232-C.
2. In the diagram above, representative software supply media and 3.5 -inch FDs.

## B. 2 EVALUATION TOOLS

To evaluate the functions of the $\mu$ PD78P324, the following tools are made available.

| Part Number | Host Machine | Function |
| :--- | :--- | :--- |
| EB-78320-98 | PC-9800 series | By connecting to a host machine, it is possible <br> to evaluate the functions equipped by the <br> $\mu$ PD78P324 in a simple manner. The com- <br> mand system of this product basically <br> conforms to that of IE-78327-R and IE-78320- <br> R. Therefore, it is easy to move to the <br> development work of application systems by <br> IE-78327-R or IE-78320-R. In addition a turbo <br> access manager ( $\mu$ PD71P301)Note can be <br> mounted on the board. |
| EB-78320-PC | IBM PC/AT or its compatible <br> machine |  |

Note The turbo access manager ( $\mu \mathrm{PD} 71 \mathrm{P} 301$ ) is a maintenance product.

Cautions 1. This product is not a development tool of $\mu$ PD78P324 application systems.
2. This product is not equipped with the emulation function for executing the PROM incorporated in the $\mu$ PD78P324.

## B. 3 EMBEDDED SOFTWARE

The following embedded software programs are available to perform program development and maintenance more efficiently.

## Eeal-time OS

| Real-time OS (RX78K/III) | The $\mathrm{RX} 78 \mathrm{~K} / \mathrm{III}$ is designed to provide a multi-task environment in the field of control application where real-time operation is required. By using this real-time OS, the performance of the whole system can be improved by allocating CPU's idle time to other processings. <br> The RX78K/III provides the system call based on the $\mu$ ITRON specifications. <br> The RX78K/III package provides tools (configurators) for creating RX78K/III's nucleus and multiple information table. |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
|  | Host machine |  |  | Part number |
|  |  | OS | Supply medium |  |
|  | PC-9800 series | MS-DOS | 3.5-inch 2HD | $\mu \mathrm{S} 5 \mathrm{~A} 13 \mathrm{RX} 78320$ |
|  |  |  | 5-inch 2HD | $\mu \mathrm{S} 5 \mathrm{~A} 10 \mathrm{RX} 78320$ |
|  | IBM PC/AT and its compatible machine | PC DOS | 3.5-inch 2 HC | $\mu$ S7B13RX78320 |
|  |  |  | 5-inch 2HC | $\mu \mathrm{S7B10RX} 78320$ |

## Caution To purchase the operating system above, you need to fill in a purchase application form beforehand and sign a contract allowing you to use the software.

Remark When using the real-time OS RX78K/III, you need the assembler package RA78K/III (optional) as well.

Fuzzy Inference Development Support System

| Fuzzy knowledge data creation tools (FE9000, FE9200) | This program supports inputting/editing/evaluating (through simulation) of the fuzzy knowledge data (fuzzy rules and membership functions). |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | Host machine | OS |  | Supply medium | Part number |
|  | PC-9800 series | MS-DOS |  | 3.5-inch 2HD | $\mu$ S5A13FE9000 |
|  |  |  |  | 5-inch 2HD | $\mu$ S5A10FE9000 |
|  | IBM PC/AT and its compatible machine | PC DOS | Winsows | 3.5-inch 2HC | $\mu$ S7B13FE9000 |
|  |  |  |  | 5-inch 2HC | $\mu$ S7B10FE9000 |
| Translator (FT78K3) ${ }^{\text {Note }}$ | This program converts the fuzzy knowledge data obtained with fuzzy knowledge data creation tools to an assembler source program for RA78K/III. |  |  |  |  |
|  | Host machine | OS |  |  | Part number |
|  |  |  |  | Supply medium |  |
|  | PC-9800 series | MS-DOS |  | 3.5-inch 2HD | $\mu$ S5A13FT78K3 |
|  |  |  |  | 5-inch 2HD | $\mu$ S5A10FT78K3 |
|  | IBM PC/AT and its compatible machine | PC DOS |  | 3.5-inch 2HC | $\mu$ S7B13FT78K3 |
|  |  |  |  | 5-inch 2HC | $\mu$ S7B10FT78K3 |
| Fuzzy inference module (FI78K/III) ${ }^{\text {Note }}$ | This program executes fuzzy inference. Fuzzy inference is executed by being linked to the fuzzy knowledge data converted by the translator. |  |  |  |  |
|  | Host machine |  |  |  | Part number |
|  |  |  | S | Supply medium |  |
|  | PC-9800 series | MS-DOS |  | 3.5-inch 2HD | $\mu$ S5A13FI78K3 |
|  |  |  |  | 5-inch 2HD | $\mu$ S5A10FI78K3 |
|  | IBM PC/AT and its compatible machine | PC DOS |  | 3.5-inch 2HC | $\mu$ S7B13FI78K3 |
|  |  |  |  | 5-inch 2HC | $\mu$ S7B10FI78K3 |
| Fuzzy inference debugger (FD78K/III) | This is a support software program for evaluating and adjusting the fuzzy knowledge data at a hardware level by using the in-circuit emulator. |  |  |  |  |
|  | Host machine |  |  |  | Part number |
|  |  |  | S | Supply medium |  |
|  | PC-9800 series | MS-DOS |  | 3.5 -inch 2HD | $\mu$ S5A13FD78K3 |
|  |  |  |  | 5-inch 2HD | $\mu$ S5A10FD78K3 |
|  | IBM PC/AT and its compatible machine | PC DOS |  | 3.5-inch 2HC | $\mu$ S7B13FD78K3 |
|  |  |  |  | 5-inch 2HC | $\mu$ S7B10FD78K3 |

Note Under development

## NOTES FOR CMOS DEVICES

## (1) PRECAUTION AGAINST ESD FOR SEMICONDUCTORS

Note: Strong electric field, when exposed to a MOS device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred. Environmental control must be adequate. When it is dry, humidifier should be used. It is recommended to avoid using insulators that easily build static electricity. Semiconductor devices must be stored and transported in an anti-static container, static shielding bag or conductive material. All test and measurement tools including work bench and floor should be grounded. The operator should be grounded using wrist strap. Semiconductor devices must not be touched with bare hands. Similar precautions need to be taken for PW boards with semiconductor devices on it.

## (2) HANDLING OF UNUSED INPUT PINS FOR CMOS

Note: No connection for CMOS device inputs can be cause of malfunction. If no connection is provided to the input pins, it is possible that an internal input level may be generated due to noise, etc., hence causing malfunction. CMOS device behave differently than Bipolar or NMOS devices. Input levels of CMOS devices must be fixed high or low by using a pull-up or pull-down circuitry. Each unused pin should be connected to VDD or GND with a resistor, if it is considered to have a possibility of being an output pin. All handling related to the unused pins must be judged device by device and related specifications governing the devices.

## (3) STATUS BEFORE INITIALIZATION OF MOS DEVICES

Note: Power-on does not necessarily define initial status of MOS device. Production process of MOS does not define the initial operation status of the device. Immediately after the power source is turned ON, the devices with reset function have not yet been initialized. Hence, power-on does not guarantee out-pin levels, I/O settings or contents of registers. Device is not initialized until the reset signal is received. Reset operation must be executed immediately after power-on for devices having reset function.

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HP9000 series 300 and HP-UX are trademarks of Hewlett-Packard.
SPARCstation is a trademark of SPARC International, Inc.
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TRON is an abbreviation of The Realtime Operating system Nucleus.
ITRON is an abbreviation of Industrial TRON.

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The customer must judge the need for license: $\mu \mathrm{PD} 78 \mathrm{P} 324 \mathrm{GJ}-5 \mathrm{BJ} /(\mathrm{A}) /(\mathrm{A} 1) /(\mathrm{A} 2) /$, 78P324LP/(A)/(A1)/(A2)

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Anti-radioactive design is not implemented in this product.


[^0]:    Cautions

    1. The PROM product and the mask ROM product differ in their noise resistance volume and noise reflection. If replacement of the PROM product with the mask ROM product in the process of trial to mass production is being considered, ensure to make a sufficient evaluation with the CS product (not ES product) of the mask ROM product.
    2. The $\mu \mathrm{PD} 78 \mathrm{P} 324(\mathrm{~A}) /(\mathrm{A} 1) /(\mathrm{A} 2)$ are one-time PROM products only. The differences between the $\mu \mathrm{PD} 78 \mathrm{P} 324(\mathrm{~A}) /(\mathrm{A} 1) /(\mathrm{A} 2)$ and the $\mu \mathrm{PD} 78324(\mathrm{~A}) /(\mathrm{A} 1) /(\mathrm{A} 2)$ are the same as those shown in the table above, except in terms of the EPROM product.
